

TPS40400

ZHCS184B - APRIL 2011 - REVISED OCTOBER 2011

3 V至 **20 V PMBUS** 同步降压控制器

查询样品: TPS40400

特性

- 输入工作电压范围: 3 V 至 20 V
- 支持 PMBus 功能的模拟控制器
- 参考电压 600 mV ± 1%
- 远程电压感测放大器
- 内部 6 V 稳压器与 6 V 栅极驱动器
- 可编程过流保护
- 电感器电阻或串行电阻适用于电流感测
- 可编程开关频率: 200 kHz 至 2 MHz
- 电源良好指示器
- 热关断
- 可编程软启动
- 内部引导二极管
- 预偏置输出安全
- 24 引脚 QFN 封装

应用范围

- 智能电源系统
- 电源模块
- 通信设备
- 计算机设备

说明

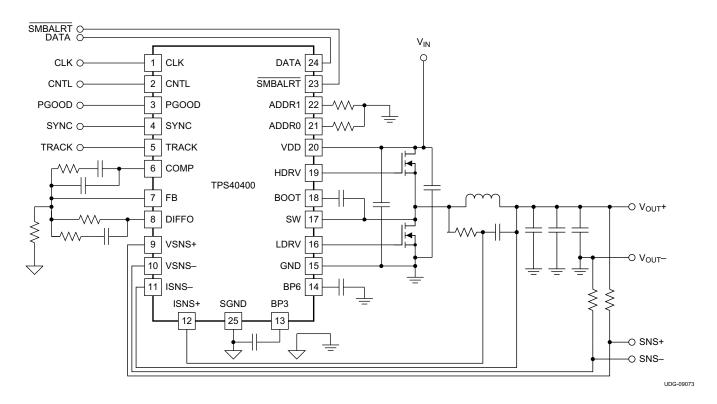
TPS40400是一款成本优化的灵活同步降压控制器, 采用 3.0 V 至 20 V 额定电源供电。该控制器是一款模拟 PWM 控制器,可通过 PMBus 接口进行编程和监控。 该器件的高灵活特性包括可编程软启动时间、可编程短 路限制以及可编程欠压锁定 (UVLO)等。该控制器是 一款模拟 PWM 控制器,可通过 PMBus 接口进行编程 和监控。该器件的高灵活特性包括可编程软启动时 间、可编程短路限制以及可编程欠压锁定 (UVLO)等。

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TEXAS INSTRUMENTS

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说明(继续)

自适应反交叉传导方案可用于避免功率 FET 出现直通电流。 栅极驱动电压为 6 V,可改进功率 FET,减少损失。 通过感应电感器上或与电感器串联电阻器上的压降,可检测短路情况。 PMBus 可编程阈值与该电压相比较,可检 测过流。 在达到过流阈值时,则可采用逐脉冲电流限制方案将电流降至可接受的水平。 如果过流情况持续超过转 换器的 7 个时钟周期,则宣布故障条件,转换器将关闭并进入短中断重启模式或锁存。 该行为可通过 PMBus 接口 选择。 其它 PMBus 接口特性还包括可编程工作频率、软起动时间、过压及欠压阈值、对有关事件的响应,以及包 括边缘效应和状态监测在内的输出电压改变等。

ORDERING INFORMATION⁽¹⁾⁽²⁾

PACKAGE	PINS	TAPE AND REEL QTY.	ORDERABLE NUMBER
Disctis OFN (DUIL)	24	250	TPS40400RHLT
Plastic QFN (RHL)	24	3000	TPS40400RHLR

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

ABSOLUTE MAXIMUM RATINGS

		VALUE	VALUE	
		MIN	MAX	UNIT
	VDD	-0.3	22	
	SW	-5	27	
	BOOT	-0.3	30	
Input voltogo rongo	BOOT-SW, HDRV-SW (Differential from BOOT or HDRV to SW)	-0.3	7	V
Input voltage range	VSNS+, TRACK, SYNC, FB	-0.3	7	v
	DATA, CLK, CNTL	-0.3	3.6	
	ISNS+, ISNS-	-0.3	15	
	VSNS-	-0.3	0.3	
	HDRV	-0.3	30	
	BP3	-0.3	3.8	
Output voltage range	BP6, COMP, PGOOD, DIFFO, LDRV	-0.3	7	V
	SMBALRT, ADDR0	-0.3	3.6	
T _J Operating junction temperature range		-40	150	°C
T _{STG} Storage tempera	-55	150	°C	

PACKAGE DISSIPATION RATINGS⁽¹⁾

PACKAGE	THERMAL IMPEDANCE JUNCTION-TO-AMBIENT (°C/W)	AIRFLOW	T _A = 25°C POWER RATING (W)	T _A = 85°C POWER RATING (W)
	31.1	Natural Convection	3.21	1.29
24-Pin Plastic QFN (RHL)	25.2	200 LFM	3.96	1.58
	23	400 LFM	4.36	1.74

 Ratings based on JEDEC High Thermal Conductivity (High K) Board. For more information on the test method, see TI Technical Brief SZZA017.

RECOMMENDED OPERATING CONDITIONS

		MIN	TYP MAX	UNIT
VDD	Input operating voltage	3.0	20	V
TJ	Operating junction temperature	-40	125	°C

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ELECTROSTATIC DISCHARGE PROTECTION

	MIN	TYP	MAX	UNIT	
Human Body Model (HBM)		2500		V	
Charged Device Model (CDM)		1500		V	

ELECTRICAL CHARACTERISTICS

Notice REFERENCE VoltAge Reference System Feedback pin voltage default settings $-40^{\circ}\text{C} \le T_{3} \le 125^{\circ}\text{C}$ 594 600 606 mV VrB(max) Feedback pin voltage maximum adjustment 780 mV VrB(max) Feedback pin voltage maximum adjustment 2.34 mV VrB(max) Feedback pin voltage adjustment resolution 2.34 mV VrB(max) Maximum nonlinearity error over adjustment resolution 2.34 mV BP6 REGULATOR 6.2 6.5 6.8 V Voos Regulator output voltage Vuop = 6 V, Ispa = 50 mA 100 mX BP6 REGULATOR 100 range 3.1 3.3 3.5 V Vpos Regulator dropout voltage, (Vvop - Vapa) Vvop = 3V, Ispa = 5 mA 100 200 mV Sego 3.3.4 3.3 3.5 V V 200 2000 2000 mV Segulator dropout voltage, (Vvop - Vapa) Vvop = 3V, Ispa = 5 mA 100 200 mV Opca Regulator dropout volt		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Integrating current Switching, no driver load 6 15 mA VoLTAGE REFERENCE	INPUT SUPF	PLY					
Bits Control	V _{VDD}	Input voltage range		3		20	V
VPs Feedback pin voltage default settings 40°C $\leq T_{j} \leq 125°C$ 594 600 606 mV VPs(ma) Feedback pin voltage minimum adjustment 750 mV VPs(ma) Feedback pin voltage adjustment resolution 2.34 mV VPs(ma) Resetback pin voltage adjustment resolution 2.34 mV VPs(ma) Maximum noninearity error over adjustment range 10 mV BPS REGULATOR 6.2 6.5 6.8 V Vps(ma) Regulator output voltage Vupo = 6 V. Issee = 50 mA 3.00 mV BPS REGULATOR 100 mA 100 mA BP3 REGULATOR 100 200 200 200 mV Sea 3.3-V regulator output voltage Vvpo = 3V, Isse = 5 mA 100 200 mV Social range Switching frequency Factory default setting 480 600 720 kHz Social range Svi Vvpo $\leq 20 V, 200 ~ K1z < f_{SW} \leq 2 MHz -20% 200 200 200 200 200 200 $	I _{VDD}	Input operating current	Switching, no driver load		6	15	mA
VP:general VP:generalFeedback pin voltage maximum adjustment750mVVP:general VP:generalFeedback pin voltage adjustment resolution2.34mVVP:general VP:general rangeFeedback pin voltage adjustment resolution2.34mVVP:general versionResplate provide adjustment resolution2.34mVVP:general range6.26.56.8VBPG REGULATORSet VersionVicon = 6 V, Isee = 50 mA300mVVp:ge Vp:ge6.26.56.8VmABP3 REGULATOR100mAmAmABP3 REGULATORVp:ge Vp:ge3.13.33.5VVp:ge Vp:ge3.3-V regulator output voltageVp:ge Vp:ge3.13.33.5VVp:ge Vp:ge3.3-V regulator output voltageVp:ge Vp:ge3.13.33.5VVp:ge Vp:ge3.3-V regulator output voltageVp:ge Vp:ge3.13.33.5VVp:ge Vp:geSitching frequency AccuracySitching frequencyRegulator dispositionmASettLATORVp:ge Vp:ge2.002.0002.0002.000VitSYNC ligh-level input voltage2.02.002.0002.000VitSYNC ligh-level input voltage0.01.00msIssinge Maximum SYNC rise time ¹¹⁰ 100ms1.00msVitSYNC rise level1.001.00msVitVitVit<	VOLTAGE R	EFERENCE	1				
Theorem Feedback pin voltage minimum adjustment 450 mV VPB(mc) Feedback pin voltage adjustment resolution 2.34 mV VPB(mc) Feedback pin voltage adjustment resolution 2.34 mV VPB(mc) Resolutation output voltage adjustment resolution 0 mV BP6 REGULATOR 6.2 6.5 6.8 V Vgoge 6-V regulator output voltage, (Vyop - Varea) Vyop = 6 V, large = 50 mA 300 mV BP3 REGULATOR 100 mA 3.3 5 V Vaca Regulator output voltage, (Vyop - Varea) Vyop = 3V, large = 5 mA 100 mA BP3 REGULATOR 100 mA 100 mV mV Vaca Regulator output voltage 100 100 mV Vaca Regulator dropout voltage, (Vyop - Varea) Vyop = 3V, large = 5 mA 100 mV OSCILLATOR 200 200 200 V V 200 200 V Social LATOR 5 Systiching frequency Factory defa	V _{FB}	Feedback pin voltage default settings	-40°C ≤ T _J ≤ 125°C	594	600	606	mV
$ \begin{array}{ c c c c c } \hline \begin{tabular}{ c c c c } \hline \begin{tabular}{ c c c c c } \hline \begin{tabular}{ c c c c c } \hline \begin{tabular}{ c c c c c c } \hline \begin{tabular}{ c c c c c c c } \hline \begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	V _{FB(max)}	Feedback pin voltage maximum adjustment			750		mV
VFR0(m) Feedback pin voltage adjustment resolution Image 2.34 mV VFR0(m) Maximum nonlinearity error over adjustment range Image	V _{FB(min)}	Feedback pin voltage minimum adjustment			450		mV
VFEINUL range IU IU IU BP6 RESOLATOR Proce 6.2 6.5 6.8 V Vape 6-V regulator output voltage Vuod 6.2 6.5 6.8 V Vape Regulator dropout voltage, (Vvod Vape) Vvod 6.1 100 mA BP3 REGULATOR 100 Vapa 3.3-V regulator output voltage Vvod 3.1 3.3 3.5 V Vapa 3.3-V regulator output voltage, (Vvod Vapa) Vvod SULATOR 100 100 vod N OSCILLATOR Regulator dropout voltage, (Vvod Vapa) Vvod SULATOR 200 2000 rdV Mominal frequency range Factory default setting 480 600 720 kHz Accuracy 3 V S Vvod S2 V, 200 kHz S f _{SW} S2 MHz -20% 20% V V Isync SYNC high-level input voltage VVvdd SVVC Sign S2 VV, 200 kHz S f _{SW} S2 MHz 2.0 V V Isync SYNC high-level input voltage VVD -2.0 V 0.6 <		Feedback pin voltage adjustment resolution			2.34		mV
Verse 6-V regulator output voltage 6.2 6.5 6.8 V VDo6 Regulator dropout voltage, (V _{VDD} – V _{BP6}) V _{VDD} = 6 V, I _{BP6} = 50 mA 300 mV Bge Regulator current limit 100 mA BP3 REGULATOR 3.1 3.3 3.5 V V _{D03} Regulator output voltage V _{VDD} = 3V, I _{BP3} = 5 mA 100 200 mV V _{D03} Regulator dropout voltage, (V _{VDD} – V _{BP3}) V _{VDD} = 3V, I _{BP3} = 5 mA 100 200 mV OSCILLATOR fsw Switching frequency range 200 2000 kHz Nominal frequency range 2.0	V _{FB(NL)}					10	mV
Loss Regulator dropout voltage, (V _{VDD} - V _{BPB}) V _{VDD} = 6 V, I _{BPB} = 50 mA 300 mV Igee Regulator current limit 100 mA BP3 REGULATOR 3.1 3.3 3.5 V Vpoa Regulator output voltage 3.1 3.3 3.5 V Vpoa Regulator dropout voltage, (V _{VDD} - V _{BP3}) V _{vDD} = 3V, I _{BP3} = 5 mA 100 200 mV OSCILLATOR Too 200 2000 2000 KHz fsw Switching frequency range Factory default setting 480 600 720 KHz Accuracy 3 V ≤ V _{vDD} ≤ 20 V, 200 kHz ≤ f _{SW} ≤ 2 MHz -20% 20% V V Accuracy 3 V ≤ V _{vDD} ≤ 0 V, 200 kHz ≤ f _{SW} ≤ 2 MHz -20% 20% V V V Issis SYNC high-level input voltage 0.4 V V V Issis Maximum SYNC rise time ⁽¹⁾ Issis 100 ms Issis Issis Nopf6.5 V _{VDD} /6.6 V _{VDD} /6.5 V _{VDD} /6.6 V _{VDD} /6.6 V _V	BP6 REGUL	ATOR	"				
Base Regulator current limit Interview	V _{BP6}	6-V regulator output voltage		6.2	6.5	6.8	V
BP3 REGULATOR Second state Second stat	V _{DO6}	Regulator dropout voltage, (V _{VDD} – V _{BP6})	V _{VDD} = 6 V, I _{BP6} = 50 mA			300	mV
Vbp3 3.3-V regulator output voltage 3.1 3.3 3.5 V Vpc3 Regulator dropout voltage, (V _{VDD} – V _{BP3}) V _{vDD} = 3V, I _{BP3} = 5 mA 100 200 mV OSCILLATOR Factory default setting 480 600 720 kHz Nominal frequency range 200 2000 2000 kHz Accuracy 3 V ≤ V _{vDD} ≤ 20 V, 200 kHz ≤ f _{SW} ≤ 2 MHz -20% 20% V VI _H SYNC high-level input voltage 2.0 V V Isymc SYNC low-level input voltage 0.0 0.0 nn Isymc SYNC rise time ⁽¹⁾ 100 nn nn tsync Minimum SYNC rise time ⁽¹⁾ 100 ns ns tsync Minimum SYNC pulse width 100 ns ns tsync Minimum SYNC pulse width 100 ns ns tsync SYNC rise time ⁽¹⁾ 100 ns ns tsync Minimum SYNC rules (1) 100 ns ns	I _{BP6}	Regulator current limit		100			mA
Non- OSCILLATORRegulator dropout voltage, (V_{VDD} - V_{BP3})V_{VDD} = 3V, I_{BP3} = 5 mA100200mVOSCILLATORfswSwitching frequency Nominal frequency rangeFactory default setting480600720 2000kHzAccuracy3 V ≤ V_{VDD} ≤ 20 V, 200 kHz ≤ f_{SW} ≤ 2 MHz-20%20%VVILSYNC high-level input voltage2.0VVVILSYNC low-level input voltage0.4VIsyncSYNC pin leakage currentVSYNC = 6 V100nAtsyncMaximum SYNC rise time ⁽¹⁾ 100100nstsyncMinimum SYNC pulse width100nstsyncMinimum SYNC pulse width100nsV_NPRamp amplitude ⁽¹⁾ 200 kHz ≤ f_{SW} ≤ 2 MHzV_V_DD/6.6V_VDD/6.8V_VDD/6.6V_LVValley voltage ⁽¹⁾ 200 kHz ≤ f_{SW} ≤ 2 MHz0.90.90.90.9PULSE WIDTH MODULATOR (PWM)200 kHz ≤ f_{SW} ≤ 2 MHz85%150%0.9torffequency200 kHz ≤ f_{SW} ≤ 2 MHz85%150%0.9PLAAXMaximum duty cycle ⁽¹⁾ (2)FREQUENCY_SWITCH = 600 kHz90%FREQUENCY_SWITCH = 20Hz75%torffequency200 kHz ≤ f_{SW} ≤ 2 MHz85%170225nstorffequency1000.9170225nstorffequencyMinimum OFF time170225ns100torffequencyMinimum OFF time170225nstorffequ	BP3 REGUL	ATOR	"				
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	V _{BP3}	3.3-V regulator output voltage		3.1	3.3	3.5	V
fswSwitching frequency Nominal frequency rangeFactory default setting480600720 720kHzNominal frequency range 200 2000 100 <td< td=""><td>V_{DO3}</td><td>Regulator dropout voltage, (V_{VDD} – V_{BP3})</td><td>$V_{VDD} = 3V$, $I_{BP3} = 5$ mA</td><td></td><td>100</td><td>200</td><td>mV</td></td<>	V _{DO3}	Regulator dropout voltage, (V _{VDD} – V _{BP3})	$V_{VDD} = 3V$, $I_{BP3} = 5$ mA		100	200	mV
Nominal frequency range20020002000Accuracy $3 \lor \lor_{VDD} \le 20 \lor, 200 kHz \le f_{SW} \le 2 MHz$ -20% 2000Vi _H SYNC high-level input voltage 2.0 V Vi _L SYNC low-level input voltage 0.4 0.4 IsyNCSYNC pin leakage current $V_{SYNC} = 6 \lor$ 100 nA t_{SRISE} Maximum SYNC rise time ⁽¹⁾ 100 nS t_{SRISE} Maximum SYNC pulse width 100 ns t_{SYNC} Minimum SYNC pulse width 100 ns V_{VLY} Valley voltage ⁽¹⁾ $rEQUENCY_SWITCH = 200 kHz$ $V_{VDD}/6.5$ $V_{VDD}/6.6$ V_{VLY} Valley voltage ⁽¹⁾ 0.9 $rEQUENCY_SWITCH = 200 kHz$ $V_{VDD}/10$ $V_{VDD}/6.6$ V_{VLY} Valley voltage ⁽¹⁾ 0.9 0.9 0.9 0.9 0.9 $PULSE WIDTH MODULATOR (PWM)$ $FREQUENCY_SWITCH = 600 kHz$ 90% 150% $V_{OFF(min)}$ Maximum OFF time $FREQUENCY_SWITCH = 20Hz$ 85% 150% $V_{OFF(min)}$ $FREQUENCY_SWITCH = 600 kHz$ 90% 170 225 $V_{OFF(min)}$ $T_{OFF(min)}$ $T_{OFF(min)}$ 170 225 ns	OSCILLATO	R	1				
Nominal frequency range2002000Accuracy $3 \lor \leq V_{VDD} \leq 20 \lor, 200 \ kHz \leq f_{SW} \leq 2 \ MHz}$ -20% 20%ViHSYNC high-level input voltage 2.0 2.0 VViLSYNC low-level input voltage 2.0 0.4 IsyncSYNC pin leakage current $V_{SYNC} = 6 \lor$ 0.4 IsyncMaximum SYNC rise time ⁽¹⁾ 100 100 tsriseMaximum SYNC pulse width 100 100 VRMPRamp amplitude ⁽¹⁾ FREQUENCY_SWITCH = 200 \ KHz $V_{VDD}/6.6$ $V_{VD}/6.8$ $V_{VD}/6.6$ VLYValley voltage ⁽¹⁾ V V V V V V VLYValley voltage ⁽¹⁾ V $200 \ kHz \leq f_{SW} \leq 2 \ MHz$ 85% 150% V PULSE WIDTH MODULATOR (PWM)FREQUENCY_SWITCH = $600 \ kHz$ 90% V V $V_{OPF}(m)$ Maximum OVFE time $FREQUENCY_SWITCH = 600 \ kHz$ 90% V V PULSE WIDTH MODULATOR (PWM)FREQUENCY_SWITCH = $600 \ kHz$ 90% V FREQUENCY_SWITCH = $600 \$	f _{SW}	Switching frequency	Factory default setting	480	600	720	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $		Nominal frequency range		200		2000	kHz
VILSYNC low-level input voltage $\sqrt{V_{IL}}$ SYNC pin leakage current $\sqrt{V_{SYNC} = 6 V}$ $\sqrt{V_{SYNC} = 6 V}$ 100 nA IsrueMaximum SYNC rise time ⁽¹⁾ 100100ns 100 nstsrueMinimum SYNC pulse width100100nsVRMPRamp amplitude ⁽¹⁾ FREQUENCY_SWITCH = 200 kHz $V_{VDD}/6.6$ $V_{VDD}/6.5$ $V_{VDD}/6.6$ VVLYValley voltage ⁽¹⁾ FREQUENCY_SWITCH = 200 kHz $V_{VDD}/10$ $V_{VDD}/9.6$ $V_{VDD}/9.2$ VVLYValley voltage ⁽¹⁾ 0.90.9150%150%PULSE WIDTH MODULATOR (PWM)FREQUENCY_SWITCH = 600 kHz90%50%150%Pulse WIDTH MODULATOR (PWM)FREQUENCY_SWITCH = 1.2 MHz85%50%50%TopFf(min)Minimum OFF timeFREQUENCY_SWITCH = 2 MHz75%50%50%Voreff(min)Minimum ofFF timeTop 0.205 (m s110225110%TopFf(min)Minimum ofFf timeTop 0.205 (m s110%10%		Accuracy	$3 \text{ V} \leq \text{V}_{\text{VDD}} \leq 20 \text{ V}, 200 \text{ kHz} \leq f_{\text{SW}} \leq 2 \text{ MHz}$	-20%		20%	
VILSYNC low-level input voltage 0.4 I_SYNCSYNC pin leakage current $V_{SYNC} = 6 V$ 100 nA I_SYNCMaximum SYNC rise time ⁽¹⁾ 100 nS t_SRISEMaximum SYNC pulse width 100 ns t_SYNCMinimum SYNC pulse width 100 ns t_SYNCMinimum SYNC pulse width 100 ns V_{RMP} Ramp amplitude ⁽¹⁾ $FREQUENCY_SWITCH = 200 \text{ kHz}$ $V_{VDD}/6.6$ $V_{VDD}/6.8$ $V_{VDD}/6.6$ V_{VLY} Valley voltage ⁽¹⁾ $FREQUENCY_SWITCH = 2000 \text{ kHz}$ $V_{VDD}/10$ $V_{VDD}/9.6$ $V_{VDD}/9.2$ V_{VLY} Valley voltage ⁽¹⁾ $200 \text{ kHz} \le f_{SW} \le 2 \text{ MHz}$ 85% 150% $FREQUENCY_SWITCH = 600 \text{ kHz}$ 90% PULSE WIDTH MODULATOR (PWM) $FREQUENCY_SWITCH = 600 \text{ kHz}$ 90% V $FREQUENCY_SWITCH = 1.2 \text{ MHz}$ 85% V D_{MAX} Maximum duty cycle ⁽¹⁾ (2) $FREQUENCY_SWITCH = 1.2 \text{ MHz}$ 85% V V $T_{OFF(min)}$ Minimum OFF time T_{O} T_{O} T_{O} T_{O} T_{O}	V _{IH}	SYNC high-level input voltage		2.0			
$\begin{array}{ c c c c c c c c c } \hline SYNC \mbox{pin leakage current} & V_{SYNC} = 0 \ V & & & & & & 100 \\ \hline V_{SYNC} = 0 \ V & & & & & 100 & & & & 100 \\ \hline t_{SRISE} & Maximum SYNC rise time^{(1)} & & & & & 100 & & & & ns \\ \hline t_{SYNC} & Minimum SYNC pulse width & & & & & & 100 & & & & ns \\ \hline V_{RMP} & Ramp amplitude^{(1)} & FREQUENCY_SWITCH = 200 \ KHz & V_{VDD}/6.6 & V_{VDD}/6.8 & V_{VDD}/6.6 & \\ \hline FREQUENCY_SWITCH = 600 \ KHz & V_{VDD}/10 & V_{VDD}/9.6 & V_{VDD}/9.2 & \\ \hline V_{VLY} & Valley voltage^{(1)} & & & & & & & & & \\ \hline f_{SYNC} & SYNC range % of nominal oscillator frequency & 200 \ KHz \le f_{SW} \le 2 \ MHz & 85\% & & & & & & & & \\ \hline PULSE \ WIDTH \ MODULATOR \ (PWM) & & & & & & & & & & \\ \hline P_{MAX} & Maximum \ duty \ cycle^{(1) \ (2)} & & & & & & & & & & & & \\ \hline f_{REQUENCY_SWITCH = 1.2 \ MHz & 85\% & & & & & & & & & & \\ \hline FREQUENCY_SWITCH = 200 \ KHz \ SYNC H = 2 \ MHz & 75\% & & & & & & & & & \\ \hline f_{REQUENCY_SWITCH = 2 \ MHz \ SS\% & & & & & & & & & & & \\ \hline f_{REQUENCY_SWITCH = 2 \ MHz \ SS\% & & & & & & & & & & & & & \\ \hline FREQUENCY_SWITCH = 2 \ MHz \ SS\% & & & & & & & & & & & & & \\ \hline f_{REQUENCY_SWITCH = 2 \ MHz \ SS\% & & & & & & & & & & & & & & \\ \hline f_{CFF(min)} \ Minimum \ OFF \ time \ ST\% & & & & & & & & & & & & & & & & & & &$	V _{IL}	SYNC low-level input voltage				0.4	V
$ \begin{array}{c c c c c c c c c } \hline V_{SYNC} = 0 \ V & 100 \\ \hline V_{SYNC} = 0 \ V & 100 \\ \hline t_{SRISE} & Maximum SYNC rise time^{(1)} & 100 & ns \\ \hline t_{SRISE} & Minimum SYNC pulse width & 100 & ns \\ \hline t_{SYNC} & Minimum SYNC pulse width & 100 & rs \\ \hline V_{RMP} & Ramp amplitude^{(1)} & FREQUENCY_SWITCH = 200 \ KHz & V_{VDD}/6.6 & V_{VDD}/6.5 & V_{VDD}/6.3 & V \\ \hline FREQUENCY_SWITCH = 600 \ KHz & V_{VDD}/7.0 & V_{VDD}/6.8 & V_{VDD}/6.6 \\ \hline FREQUENCY_SWITCH = 2000 \ KHz & V_{VDD}/10 & V_{VDD}/9.6 & V_{VDD}/9.2 \\ \hline V_{VLY} & Valley \ voltage^{(1)} & 0.9 & 0.9 \\ \hline V_{VLY} & Valley \ voltage^{(1)} & 0.9 & 150\% \\ \hline PULSE \ WIDTH \ MODULATOR \ (PWM) \\ \hline D_{MAX} & Maximum \ duty \ cycle^{(1) \ (2)} & FREQUENCY_SWITCH = 600 \ KHz & 90\% & FREQUENCY_SWITCH = 1.2 \ MHz & 85\% & 150\% \\ \hline FREQUENCY_SWITCH = 1.2 \ MHz & 85\% & 170 & 225 \ ns \\ \hline t_{OFF(min)} & Minimum \ OFF \ time & To 200 \ frequency \ To 200 \ MID \ MID \ MID \ To 200 \ MID \ To 200 \ MID $			V _{SYNC} = 6 V			100	
$\begin{array}{c c c c c c c } \hline \text{Minimum SYNC pulse width} & 100 & ns \\ \hline t_{\text{SYNC}} & \text{Minimum SYNC pulse width} & FREQUENCY_SWITCH = 200 kHz & V_{VDD}/6.6 & V_{VDD}/6.5 & V_{VDD}/6.3 & V \\ \hline FREQUENCY_SWITCH = 200 kHz & V_{VDD}/7.0 & V_{VDD}/6.8 & V_{VDD}/6.6 & FREQUENCY_SWITCH = 2000 kHz & V_{VDD}/7.0 & V_{VDD}/6.8 & V_{VDD}/9.2 & V_{VLY} & Valley voltage(1) & 0.9 &$	SYNC	SYNC pin leakage current	V _{SYNC} = 0 V			100	nA
FREQUENCY_SWITCH = 200 kHz $V_{VDD}/6.6$ $V_{VDD}/6.5$ $V_{VDD}/6.3$ V V_{RMP} Ramp amplitude ⁽¹⁾ FREQUENCY_SWITCH = 600 kHz $V_{VDD}/7.0$ $V_{VDD}/6.8$ $V_{VDD}/6.6$ $FREQUENCY_SWITCH = 2000 kHz$ $V_{VDD}/10$ $V_{VDD}/9.6$ $V_{VDD}/9.2$ V_{VLY} Valley voltage ⁽¹⁾ 0.90.9 f_{SYNC} SYNC range % of nominal oscillator frequency200 kHz $\leq f_{SW} \leq 2$ MHz85%150%PULSE WIDTH MODULATOR (PWM)FREQUENCY_SWITCH = 600 kHz90%FREQUENCY_SWITCH = 600 kHz90%FREQUENCY_SWITCH = 600 kHz90%FREQUENCY_SWITCH = 1.2 MHz85%TO STOC TO	t _{SRISE}	Maximum SYNC rise time ⁽¹⁾		100			ns
$V_{RMP} Ramp amplitude^{(1)} \qquad FREQUENCY_SWITCH = 600 \text{ kHz} \qquad V_{VDD}/7.0 V_{VDD}/6.8 V_{VDD}/6.6 \\ FREQUENCY_SWITCH = 2000 \text{ kHz} \qquad V_{VDD}/10 V_{VDD}/9.6 V_{VDD}/9.2 \\ \hline V_{VLY} Valley voltage^{(1)} \qquad 0.9 0.9 \\ \hline f_{SYNC} SYNC range % of nominal oscillator frequency \\ f_{SYNC} SYNC range % of nominal oscillator frequency \\ \hline DULSE WIDTH MODULATOR (PWM) \\ PULSE WIDTH MODULATOR (PWM) \\ PMAx \qquad Maximum duty cycle^{(1) (2)} \qquad FREQUENCY_SWITCH = 600 \text{ kHz} \qquad 90\% - \\ FREQUENCY_SWITCH = 1.2 \text{ MHz} \qquad 85\% - \\ FREQUENCY_SWITCH = 1.2 \text{ MHz} \qquad 85\% - \\ FREQUENCY_SWITCH = 2 \text{ MHz} \qquad 75\% - \\ \hline t_{OFF(min)} Minimum OFF time \qquad - \\ Tr = 2000 \text{ fm} = 2000 f$	t _{SYNC}	Minimum SYNC pulse width		100			ns
$\begin{tabular}{ c c c c c c } \hline FREQUENCY_SWITCH = 2000 \ kHz & V_{VDD}/10 & V_{VDD}/9.6 & V_{VDD}/9.2 \\ \hline V_{VLY} & Valley \ voltage^{(1)} & 0.9 & 0.9 & 0.9 \\ \hline f_{SYNC} & SYNC \ range \ % \ of \ nominal \ oscillator \ frequency & 200 \ kHz \le f_{SW} \le 2 \ MHz & 85\% & 150\% \\ \hline PULSE WIDTH \ MODULATOR \ (PWM) & FREQUENCY_SWITCH = 600 \ kHz & 90\% & FREQUENCY_SWITCH = 600 \ kHz & 85\% & 0.9 &$			FREQUENCY_SWITCH = 200 kHz	V _{VDD} /6.6	V _{VDD} /6.5	V _{VDD} /6.3	V
V _{VLY} Valley voltage ⁽¹⁾ 0.9 f_{SYNC} SYNC range % of nominal oscillator frequency 200 kHz ≤ $f_{SW} ≤ 2$ MHz 85% 150% PULSE WIDTH MODULATOR (PWM) FREQUENCY_SWITCH = 600 kHz 90% 100% D_{MAX} Maximum duty cycle ⁽¹⁾ (2) FREQUENCY_SWITCH = 1.2 MHz 85% 10% $f_{OFF(min)}$ Minimum OFF time FREQUENCY_SWITCH = 2 MHz 75% 170 225 ns	V _{RMP}	Ramp amplitude ⁽¹⁾	FREQUENCY_SWITCH = 600 kHz	V _{VDD} /7.0	V _{VDD} /6.8	V _{VDD} /6.6	
f_{SYNC} SYNC range % of nominal oscillator frequency $200 \text{ kHz} \le f_{SW} \le 2 \text{ MHz}$ 85% 150% PULSE WIDTH MODULATOR (PWM) FREQUENCY_SWITCH = 600 kHz 90% FREQUENCY_SWITCH = 600 kHz 90% FREQUENCY_SWITCH = 1.2 MHz 85% FREQUENCY_SWITCH = 1.2 MHz 85% FREQUENCY_SWITCH = 2 MHz 75% to FREQUENCY_SWITCH = 2 MHz 75% to FREQUENCY_SWITCH = 2 MHz 75% To 225 ns			FREQUENCY_SWITCH = 2000 kHz	V _{VDD} /10	V _{VDD} /9.6	V _{VDD} /9.2	
f_{SYNC} SYNC range % of nominal oscillator frequency 200 kHz $\leq f_{SW} \leq 2$ MHz 85% 150% PULSE WIDTH MODULATOR (PWM) FREQUENCY_SWITCH = 600 kHz 90% FREQUENCY_SWITCH = 600 kHz 90% FREQUENCY_SWITCH = 1.2 MHz 85% FREQUENCY_SWITCH = 1.2 MHz 85% FREQUENCY_SWITCH = 2 MHz 75% toFF(min) Minimum OFF time 170 225 ns	V _{VLY}	Valley voltage ⁽¹⁾			0.9		
D _{MAX} Maximum duty cycle ^{(1) (2)} FREQUENCY_SWITCH = 600 kHz 90% Image: Comparison of the state	-	SYNC range % of nominal oscillator frequency	200 kHz ≤ f _{SW} ≤ 2 MHz	85%		150%	
D _{MAX} Maximum duty cycle ^{(1) (2)} FREQUENCY_SWITCH = 1.2 MHz 85% FREQUENCY_SWITCH = 2 MHz 75% t _{OFF(min)} Minimum OFF time 170 225 ns	PULSE WID	TH MODULATOR (PWM)					
FREQUENCY_SWITCH = 2 MHz 75% topF(min) Minimum OFF time 170 225 ns			FREQUENCY_SWITCH = 600 kHz	90%			
FREQUENCY_SWITCH = 2 MHz 75% topF(min) Minimum OFF time 170 225 ns	D _{MAX}	Maximum duty cycle ⁽¹⁾ (2)	FREQUENCY_SWITCH = 1.2 MHz	85%			
t _{OFF(min)} Minimum OFF time 170 225 ns			FREQUENCY_SWITCH = 2 MHz	75%			
	t _{OFF(min)}	Minimum OFF time			170	225	ns
		Minimum controllable pulse ⁽¹⁾	T _J = 25°C, f _{SW} = 600 kHz			75	ns

Ensured by design. Not production tested.
 Operation at 3 V reduces maximum duty cycle by approximately 5%.





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ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SOFT-STAR	т					
	Soft-start time (3)	Factory default setting	2.7	3.1	3.5	ms
t _{SS}	Accuracy	600 μs ≤ t _{SS} ≤ 9 ms	-15%		15%	
ERROR AM	PLIFIER		·			
GBWP	Gain bandwidth product ⁽⁴⁾		15	20		MHz
A _{OL}	DC gain ⁽⁴⁾		60			dB
I _{IBFB}	Input bias current: FB (out of pin)		0		100	nA
I _{IBT}	Input bias current: TRACK (out of pin)		0		250	nA
IEAOP	Output source current	$V_{FB} = 0 V, V_{COMP} \ge 2 V$	1			
I _{EAOM}	Output sink current	$V_{FB} = 2 \text{ V}, V_{COMP} \leq 0.3 \text{ V}$	1			mA
V _{COMPH}	Error amplifier high output voltage	V _{FB} = 0 V	3.8			V
V _{COMPL}	Error amplifier low output voltage	V _{FB} = 2 V			50	mV
V _{TRACK(ofst)}	TRACK pin offset voltage		-5		+5	mV
CURRENT S	SENSE AMPLIFIER		·			
I _{ISNS+}	ISNS+ bias current				200	nA
I _{ISNS-}	ISNS- bias current				100	μA
VICM	Input common mode range		0.45		15	V
AO _{CM}	Common mode gain				-80	dB
V _{LIN}	Input linear range, VISNS+ - VISNS- ⁽⁵⁾		-45		110	mV
CURRENT L	IMIT PROTECTION					
t _{OFF}	Off time between restart attempts			6 × t _{SS}		ms
	$V_{CS+} - V_{CS-}$ voltage that trips OC fault function	Factory default settings ⁽⁵⁾ , $T_J = 25^{\circ}C$	27	30	33	mV
	Threshold accuracy	$\begin{array}{l} 3 \hspace{0.1cm} V \leq V_{VDD} \leq 20 \hspace{0.1cm} V, \\ 30 \hspace{0.1cm} mV \leq V_{ILIMTH} \leq 110 \hspace{0.1cm} mV, \hspace{0.1cm} T_J = 25 \hspace{0.1cm}^{\circ} C \end{array}$	-10%		10%	
V _{ILIMTH}		$\begin{array}{l} 3V \leq V_{VDD} \leq 20 \ V, \ V_{ILIMTH} \leq 30 \ mV, \\ T_J = 25^{\circ}C \end{array}$	-3		3	mV
	Comparator offset	$V_{ILIMTH} = 30 \text{ mV}, T_J = 25^{\circ}\text{C}$	-3		3	mV
	Temperature coefficient ⁽⁴⁾			4000		ppm/°C
t _{DLYOC}	Overcurrent delay	3-mV overdrive, $T_J = 25^{\circ}C$		155		ns
	$V_{\text{CS+}} - V_{\text{CS-}}$ voltage that sets warning status	Factory default settings, $T_J = 25^{\circ}C$	12	15	18	mV
	Threshold accuracy	$\begin{array}{l} 3 \hspace{0.1cm} V \leq V_{VDD} \leq 20V, \\ 1.9 \hspace{0.1cm} mV \leq V_{ILIMTH} \leq 120 \hspace{0.1cm} mV, \hspace{0.1cm} T_{J} = 25^{\circ}C \end{array}$	-10%		10%	
VILIMW		$\begin{array}{l} 3V \leq V_{VDD} \leq 20 \ V, \ V_{ILIMTH} < 30 \ mV, \\ T_{J} = 25^{\circ}C \end{array}$	-3		3	mV
	Comparator offset	$V_{ILIMTH} = 20 \text{ mV}, \text{T}_{J} = 25^{\circ}\text{C}$	-3		3	mV
	Temperature coefficient ⁽⁴⁾			4000		ppm/°C
t _{DLYOCW}	Overcurrent warning delay ⁽⁴⁾	3-mV overdrive		250		ns

(3) See applications section for more information regarding soft-start time setting.

(4) Ensured by design. Not production tested.

(5) The entire current ripple waveform must reside inside the linear range for current reading results to be accurate. DC current level must be zero or greater for accurate results. Current sense does not support applications that sink current. Transient voltages (such as ripple) are permitted to go below 0 V, but must be within the specified linear range.

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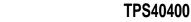
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ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise stated, these	specifications apply for $-40^{\circ}C \le 1$	L≤ 125°C, Vpp= 12 Vdc	, FREQUENCY_SWITCH = 600 kHz
	c = 1	$J = 1200, v_{DD} = 12, v_{00}$	

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT DR						
R _{HDHI}	High-side driver pull up resistance	$(V_{BOOT} - V_{SW}) = 6.4 \text{ V}, I_{HDRV} = -100 ,$ $T_J = 25^{\circ}\text{C}$		1.25	2.5	
R _{HDLO}	High-side driver pull down resistance	$(V_{BOOT} - V_{SW}) = 6.4 \text{ V}, I_{HDRV} = 100 \text{ mA}, T_J = 25^{\circ}\text{C}$		1.3	2.6	Ω
R _{LDHI}	Low-side driver pull up resistance	$T_J = 25^{\circ}C$		1.25	2.5	
R _{LDLO}	Low-side driver pull down resistance	$T_J = 25^{\circ}C$		0.8	1.5	
t _{HRISE}	High-side driver rise time ⁽⁶⁾			6	12.1	
t _{HFALL}	High-side driver fall time ⁽⁶⁾			6.3	12.6	
t _{LRISE}	Low-side driver rise time (6)	$-C_{LOAD} = 2.2 \text{ nF}$		6	12.1	ns
t _{LFALL}	Low-side driver fall time (6)			4	8	
t _{DT}	Anti-cross conduction time	MFR_SPECIFIC_00 bit 0 = 0, (short dead time.)	20		50	ns
I _{SW}	SW pin leakage current (out of pin)	V _{SW} = 0 V			1	μA
BOOTSTRAF	P					
V _{BOOT}	Internal diode voltage drop	I _{BOOT} = 5 mA		0.7	1	V
I _{BOOT(lk)}	BOOT diode leakage current ⁽⁶⁾	$(V_{BOOT} - V_{SW}) = 6 V$		1		μA
UVLO			·		·	
	VDD UVLO turn on threshold ⁽⁷⁾	Factory default settings (minimum)	2.475	2.750	3.025	
V _{UVLO(on)}	Accuracy ⁽⁷⁾	2.25 V \leq V _{VDD} \leq 20 V, 2.75 V \leq VIN_ON \leq 18 V	-10%		10%	V
	VDD UVLO turn off threshold ⁽⁷⁾	Factory default settings (minimum)	2.25	2.5	2.75	
V _{UVLO(off)}	Accuracy ⁽⁷⁾	2.25 V < V _{VDD} < 20 V, 2.75 V < VIN_OFF < 17.6 V	-10%		10%	V
REMOTE VO	LTAGE SENSE AMPLIFIER					
VIOFST	Input offset voltage		-10		10	mV
R _{GAIN}	Gain setting resistor ⁽⁶⁾		48	60	72	kΩ
		V _{VDD} > 6.5 V	0		6	
V _{DIFFO}	Output voltage at DIFFO pin	V _{VDD} = 5 V	0		4.5	V
		V _{VDD} = 3 V	0		2.5	
K _{DIFF}	Differential gain of amplifier		0.995	1.000	1.005	V/V
V _{AGBWP}	Closed loop bandwidth ⁽⁶⁾		2			MHz
IVAOP	Output source current	$V_{SNS+} = V_{DIFFO} = 5 V, V_{SNS-} = 0 V$	1			mA
I _{VAOM}	Output sink current	$V_{SNS+} = 0 \text{ V}, V_{SNS-} = 4.5 \text{ V}, V_{DIFFO} = 5 \text{ V}$	1			mA
POWERGOO	DD					
	FB pin voltage upper limit for power good on	Factory default actings		648		m\/
V _{PGON}	FB pin voltage lower limit for power good on	Factory default settings		552		mV
	Accuracy	540 mV < V _{PGON} < 660 mV	-5%		5%	
	FB pin voltage upper limit for power good off			660		mV
V _{PGOFF}	FB pin voltage lower limit for power good off	Factory default settings		540		
	Accuracy	528 mV < V _{PGOFF} < 672 mV	-5%		5%	
R _{PGD}	Pull down resistance of PGD pin	$V_{FB} = 0, I_{PGOOD} = 5 \text{ mA}$			50	Ω
I _{PGDLK}	Leakage current	Factory default settings , 550 mV < V _{FB} < 650 mV, V _{PGOOD} = 5 V	3		15	μA
t _{PGD}	Delay filter from FB ⁽⁶⁾			5		μs

(6) Ensured by design. Not production tested.
(7) Although specifications appear to overlap, hysteresis is assured for UVLO turn on and turn off thresholds.



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ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise stated, these specifications apply for $-40^{\circ}C \le T_J \le 125^{\circ}C$, $V_{DD}= 12$ Vdc, FREQUENCY_SWITCH = 600 kHz

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OUTPUT VO	LTAGE MARGINING					
	VFB slope during margin voltage transition (8)	Factory default settings	250	214	188	V/s
MRG _{SLP}	Accuracy	$3 \text{ V} < \text{V}_{\text{VDD}} < 20 \text{ V}, 600 \ \mu\text{s} < \text{t}_{\text{SS}} < 9 \ \text{ms}$	-15%		15%	
V _{FBMH}	FB pin voltage after margin high command	Factory default settings	650	660	670	mV
V _{FBML}	FB pin voltage after margin low command	Factory default settings	532	540	548	mV
V _{FBM(max)}	Maximum FB pin voltage with Margin	–40°C < T _J < 125°C	742	750	758	mV
V _{FBM(min)}	Minimum FB pin voltage with Margin	–40°C < T _J < 125°C	445	450	455	mV
V _{FB(inc)}	Resolution of FB steps with margin			2.34		mV
OVERVOLTA	GE AND UNDERVOLTAGE DETECTION					
	FB pin overvoltage threshold (OV flag)	Factory default settings	638	672	705	
V _{OV}	Accuracy	3 V < V _{VDD} < 20 V, 648 mV < V _{OV} < 690 mV	-5%		5%	mV
	FB pin undervoltage threshold (UV flag)	Factory default settings	502	528	554	
V _{UV}	Accuracy	3 V < V _{VDD} < 20 V, 510 mV < V _{OV} < 552 mV	-5%		5%	mV
MBus INTE	RFACE					
V _{IH}	High-level input voltage, CLK, DATA, CNTL		2.1			V
VIL	Low-level input voltage, CLK, DATA, CNTL				0.8	V
	High-level input current, CLK, DATA, CNTL		-10		10	
IH	CNTL		-12		10	μA
	Low-level input current, CLK, DATA, CNTL		-10		10	
IL	CNTL		-12		10	μA
V _{OL}	Low-level output voltage, DATA, SMBALRT	$3.0 \text{ V} \le \text{V}_{\text{VDD}} \le 20 \text{ V}, \text{ I}_{\text{OUT}} = 2 \text{ mA}$			0.4	V
ОН	High-level open drain leakage current, DATA, SMBALRT	V _{OUT} = 3.6 V	0		10	μA
Co ⁽⁸⁾	Pin capacitance, CLK, DATA			0.7		pF
PMB	PMBus operating frequency range	Slave mode	10		400	kHz
BUF	Bus free time between START and STOP ⁽⁸⁾		4.7			μs
HD:STA	Hold time after repeated START ⁽⁸⁾		4.0			μs
SU:STA	Repeated START setup time ⁽⁸⁾		4.7			μs
SU:STO	STOP setup time ⁽⁸⁾		4.0			μs
	Data hold time ⁽⁸⁾	Receive mode	0			
HD:DAT	Data noid time.	Transmit mode	300			ns
SU:DAT	Data setup time ⁽⁸⁾		250			ns
TIMEOUT	Error signal/detect ⁽⁸⁾		25		35	μs
LOW:MEXT	Cumulative clock low master extend time ⁽⁸⁾				50	μs
LOW:SEXT	Cumulative clock low slave extend time ⁽⁸⁾				25	μs
LOW	Clock low time ⁽⁸⁾		4.7			μs
HIGH	Clock high time ⁽⁸⁾		4.0			μs
FALL	CLK/DATA fall time ⁽⁸⁾				300	ns
RISE	CLK/DATA rise time ⁽⁸⁾				1000	ns
PMBus ADD	RESSING	· · · · · · · · · · · · · · · · · · ·				
ADD	ADDX pin current		8.23	9.75	11.21	μA
V _{ADD(L)}	Address pin illegal low voltage threshold				0.055	V

(8) Ensured by design. Not production tested.

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ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise stated, these specifications apply for −40°C ≤ T_J ≤ 125°C, V_{DD}= 12 Vdc, FREQUENCY_SWITCH = 600 kHz

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
MEASUREME	NT SYSTEM		I			
t _{IDLY}	Read delay time ⁽⁹⁾		153	192	231	μs
I _{RES}	Current measurement resolution (LSB) (10) (11)			122		μV
I _{RNG}	Current measurement range ⁽¹¹⁾ (12)		-45		110	mV
I _{ACC}	Gain accuracy ⁽¹³⁾		-3%		3%	
I _{OFST}	Offset		-3		3	mV
V _{OUT(res)}	VOUT measurement resolution (LSB)			15.625		mV
V _{OUT(rng)}	VOUT voltage measurement range		0		14	V
V _{OUT(gain)}	Gain accuracy ⁽¹³⁾⁽¹⁴⁾		-2		2	LSB
V _{OUT(gain_adj)}	Gain adjustment range through PMBus		-10%		10%	
V _{OUT(ofst)}	Offset ⁽¹³⁾⁽¹⁴⁾		-3%		3%	
V _{OUT(ofst_adj)}	Gain adjustment range through PMBus		-125		124	mV
V _{IN(res)}	V _{IN} measurement resolution			32.5		mV
V _{IN(rng)}	V _{IN} voltage measurement range		3.0		20	V
V _{IN(gain)}	Gain accuracy ⁽¹³⁾⁽¹⁴⁾		-2%		2%	
V _{IN(gain_adj)}	Gain adjustment range through PMBus		-10%		10%	
V _{IN(offst)}	Offset ⁽¹³⁾⁽¹⁴⁾		-5.5	-2	1.4	LSB
V _{IN(offst_adj)}	Offset adjustment range through PMBus		-2		1.968	V
THERMAL SH	UTDOWN				·	
T _{JSD}	Junction OT shutdown temperature ⁽¹⁴⁾		135	145	155	°C
T _{JSDH}	Shutdown hysteresis ⁽¹⁴⁾		25	30	35	°C
T _{JWRN}	Junction OT warning threshold ⁽¹⁴⁾		120	130	140	°C
T _{JWRNH}	Junction OT warning temperature hysteresis ⁽¹⁴⁾		15	20	25	°C

(9) All read backs are an average of 16 consecutive measurements - not a rolling average. Time is a delay between parameter updates.

(10) Constrained by the resolution of READ_IOUT command. This presents as the greater of 122 μV/ IOUT_CAL_GAIN or 62.5 mA, the resolution of the READ_IOUT command

(11) Voltage is converted to current by dividing by IOUT_CAL_GAIN, the effective value of the resistance used to sense current in the application. Maximum amount that can be reported via PMBus is 64A.

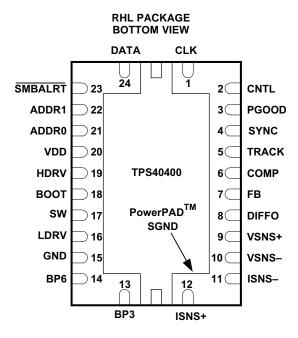
(12) Current reading is only supported to 0 average. Voltage transients to -45mV are taken into account when computing this average.

(13) PMBus commands provide for calibration of each device on an individual basis for improved overall system accuracy.

(14) Ensured by design. Not production tested.



DEVICE INFORMATION



PIN FUNCTIONS

PIN		I/O	DESCRIPTION
NAME	NO.	1/0	DESCRIPTION
ADDR0	21	Ι	Low-order address pin for PMBus address configuration. One of eight resistor values must be connected from this pin to SGND to select the low-order octal digit in the PMBus address.
ADDR1	22	Ι	High-order address pin for PMBus address configuration. One of eight resistor values must be connected from this pin to SGND to select the high-order octal digit in the PMBus address.
BOOT	18	Ι	Gate drive voltage for the high-side N-channel MOSFET. A capacitor 100 nF typical must be connected between this pin and SW.
BP3	13	0	Bypass pin for the internal regulator that supplies power to the internal controls of the device. Normal regulation voltage is 3.3 V. Connect a 100 nF or larger capacitor from this pin to GND.
BP6	14	0	Bypass pin for the internal regulator that supplies power to the gate drivers. Normal regulation voltage is 6.5 V. Connect a 1-µF or larger capacitor from this pin to GND.
CLK	1	Ι	Clock input for the PMBus interface
CNTL	2	Logic level input that controls the startup and shutdown of the converter, Exact functionality is determ PMBus options.	
COMP	6	0	Output of the error amplifier. Used for control loop compensation.
DATA	24	I/O	Data I/O for the PMBus interface
DIFFO	8	0	Output of the unity gain remote voltage sense amplifier. Typically connected to the voltage divider on FB
FB	7	-	Inverting input to the error amplifier. A voltage divider is connected here to sense the output voltage.
GND	15	-	Common connection for the device. This pin should connect to the thermal pad under the device package and to the power stage ground, preferably close to the source of the Low-side or rectifier FET. Connections should be arranged so that no power level current slow across the pad connected to the thermal pad on the underside of the device.
HDRV	19	0	Gate drive signal to the high-side FET
ISNS-	11	-	Inverting input to the current sense amplifier
ISNS+	12	Ι	Non-inverting input to the current sense amplifier
LDRV	16	0	Output used to drive the gate of the low-side or rectifier FET.
PGOOD	3	0	Power good output. This is an open drain output that pulls low when any fault condition exists within the device or when the device is not operating within a user selectable operating range of the nominal output voltage of the converter.

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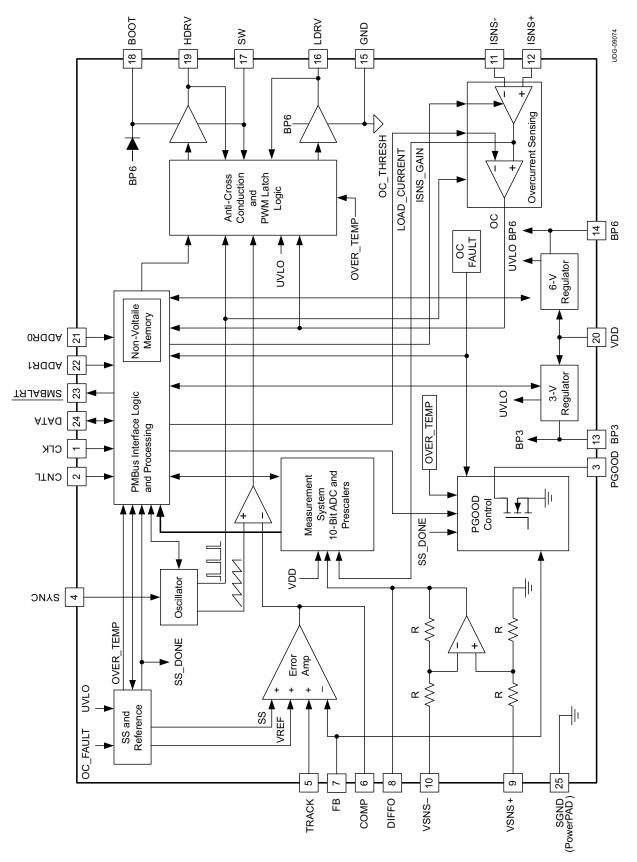
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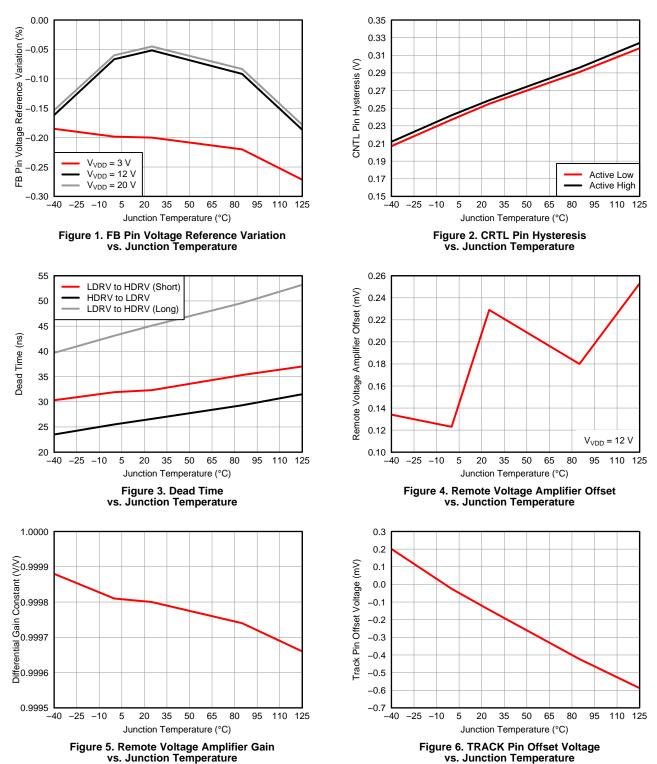
PIN FUNCTIONS (continued)

PIN		1/0	DESCRIPTION						
NAME	NO.	1/0	DESCRIPTION						
SGND	PAD	-	Signal ground for the controller. Connect the ground of signal level circuits to this pin. Connections should be arranged so that power level currents do not flow in the pad attached to the thermal plane or in the SGND portion of the circuit.						
SMBALRT	23	0	Output used to signal that PMBus host that the controller needs attention.						
SW	17	I	This is the common connection for the flying high-side FET driver and also serve as a sense line for the adaptive anti-cross-conduction circuitry						
SYNC	4	I	Logic level input to the oscillator inside the controller. The oscillator resets on the rising edge of a pulse train applied to this pin and begin a new switching cycle.						
TRACK	5	I	Analog input to the non inverting side of the control loop error amplifier. The error amplifier has three inputs (voltage reference, TRACK and soft-start ramp) to it's "+" side, and the lowest voltage applied to these three inputs dominate and control the output voltage of the whole converter. This pin is to allow the user to configure a voltage divider that allows the controller output follow an external reference voltage during startup.						
VDD	20	I	Input power connection for the device. 3.0 V to 20 V required.						
VSNS+	9	I	Non-inverting input to the unity gain remote voltage sense amplifier.						
VSNS-	10	I	Inverting input to the unity gain remote voltage sense amplifier.						

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FUNCTIONAL BLOCK DIAGRAM

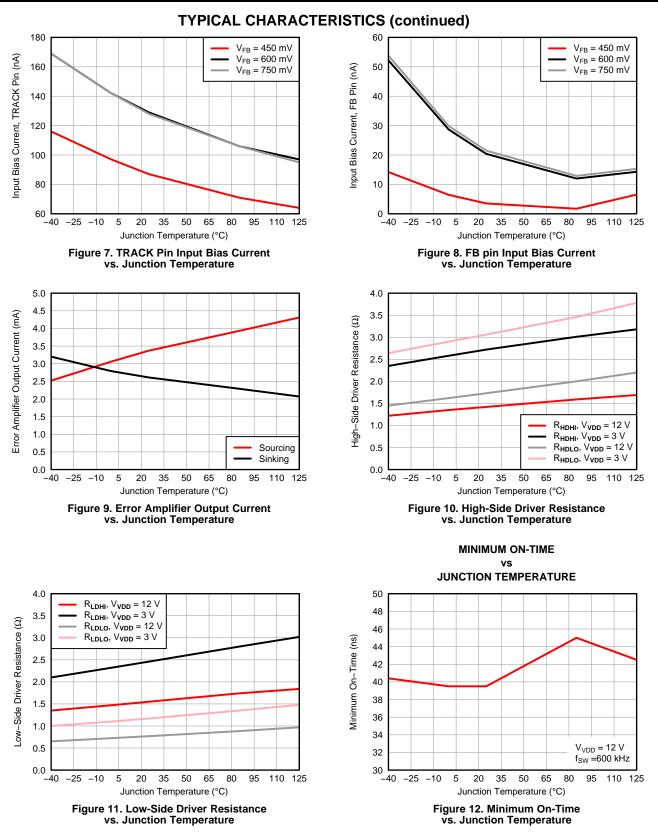




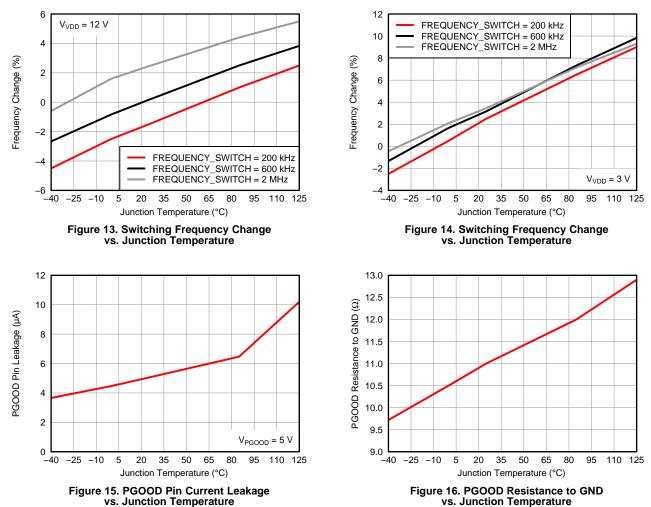
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS (continued)



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APPLICATION INFORMATION

PMBus

General Description

Timing and electrical characteristics of the PMBus can be found in the PMB Power Management Protocol Specification, Part 1, revision 1.1 available at http://pmbus.org. The TPS40400 supports both the 100 kHz and 400 kHz bus timing requirements. The TPS40400 does not stretch pulses on the PMBus when communicating with the master device.

Communication over the TPS40400 device PMBus interface can either support the Packet Error Checking (PEC) scheme or not. If the master supplies CLK pulses for the PEC byte, it is used. If the CLK pulses are not present before a STOP, the PEC is not used.

The TPS40400 supports a subset of the commands in the PMBus 1.1 specification. Most all of the controller parameters can be programmed using the PMBus and stored as defaults for later use. All commands that require data input or output use the literal format. The exponent of the data words is fixed at a reasonable value for the command and altering the exponent is not supported. Direct format data input or output is not supported by the TPS40400. See the SUPPORTED COMMANDS section for specific details.

The TPS40400 also supports the SMBALERT response protocol. The SMBALERT response protocol is a mechanism by which a slave (the TPS40400) can alert the bus master that it wants to talk. The master processes this event and simultaneously accesses all slaves on the bus (that support the protocol) through the alert response address. Only the slave that caused the alert acknowledges this request. The host performs a modified receive byte operation to get the slave's address. At this point, the master can use the PMBus status commands to query the slave that caused the alert. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The TPS40400 contains non-volatile memory that is used to store configuration settings and scale factors. The settings programmed into the device are not automatically saved into this non-volatile memory though. The STORE_DEFAULT_ALL command must be used to commit the current settings to non-volatile memory as device defaults. The settings that are capable of being stored in non-volatile memory are noted in their detailed descriptions.

Setting up the Controller – Hardware Connections

The TPS 40400 is an analog controller, meaning that it uses traditional analog circuitry to control the output of the converter. Many of the operating parameters are set using the PMBus interface. This section describes how to set the controller parameters in an application.

Output voltage. The output voltage is set in a very similar to the way to a traditional analog controller using a voltage divider from the output to the feedback (FB) pin. The output voltage must be divided down to the nominal reference voltage of 600mV. Figure 17 shows the typical connections for the controller. The voltage at the load can be sensed using the unity gain differential voltage sense amplifier. This provides better load regulation for output voltages lower than 5V nominal (see electrical specifications for the maximum output voltage directly to the differential sense amplifier). For output voltages above this level, connect the output voltage. In this case, it is also recommended to connect VSNS+ to BP3 and VSNS- to GND. If desired the differential amplifier may also be used elsewhere in the overall system as a voltage buffer provided the electrical specifications are not exceeded



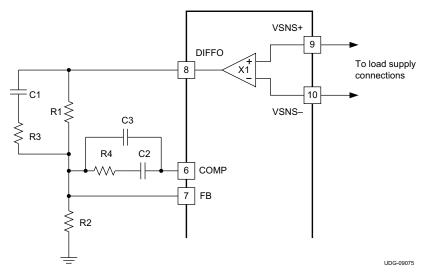


Figure 17. Setting the Output Voltage

The components in Figure 17 that determine the nominal output voltage are R1 and R2. R1 is normally chosen to make the feedback compensation values (R3, R4, C1, C2 andC3) come close to readily available standard values. R2 is then calculated in Equation 1.

$$R2 = V_{FB} \times \left(\frac{R1}{\left(V_{OUT} - V_{FB}\right)}\right)$$

where

- V_{FB} is the feedback voltage
- V_{OUT} is the desired output voltage
- · R1 and R2 are in the same units

(1)

The feedback voltage can be changed $\pm 25\%$ from the nominal 600mV using PMBus commands. This allows the output voltage to vary by the same percentage. See the PMBus Functionality and Additional Setup section for further details. Once the output voltage is set and the values of R1 and R2 are known, the VOUT_SCALE LOOP parameter can be calculated. This parameter is required for the PMBus interface to function properly when making output voltage adjustments.

Voltage feed forward. The TPS40400 has input voltage feed forward that maintains a constant power stage gain as input voltage varies and provides for very good response to input voltage transient disturbances. The simple constant power stage gain of the controller greatly simplifies feedback loop design because loop characteristics remains constant as the input voltage changes, unlike a buck converter without voltage feed forward. For modeling purposes, the gain from the COMP pin to the average voltage at the input of the L-C filter is 6V/V.

Output current limit and warning. The TPS40400 uses a differential current sense scheme to sense the output current. The sense element can be either the series resistance of the power stage filter inductor or a separate current sense resistor. When using the inductor series resistance as in Figure 18, a filter must be used to remove the large AC component of voltage across the inductor and leave only the component of the voltage that appears across the resistance of the inductor. The values of R5 and C4 for the ideal case can be found by Equation 2. The time constant of the R-C filter should be equal to or greater than the time constant of the inductor itself. If the time constants are equal, the voltage appearing across C4 is be the current in the inductor multiplied the inductor resistance. The inductor ripple current is reflected in the voltage across C4 perfectly in this case and there is no reason to have a shorter R-C time constant. The time constant of the R-C filter can be made longer than the inductor time constant because this is a voltage mode controller and the current sensing is done for overcurrent detection and output current reporting only. Extending the R-C filter time constant beyond the inductor time constant lowers the AC ripple component of voltage present at the ISNS pins of the TPS40400 but leaves the correct DC current information intact. This also delays slightly the response to an overcurrent event, but reduces noise in the system leading to cleaner overcurrent performance and current reporting data over the PMBus



$$R5 \times C4 \ge \left(\frac{L}{R_{ESR}}\right)$$

where (from Figure 18)

- R5 and R_{ESR} are in Ω
- C4 is in F (suggest 100 nF, 10⁻⁷F)
- L is in H

(2)

The maximum voltage that the TPS40400 is designed to accept across the ISNS pins is 110 mV. Because most all inductors have a copper conductor and because copper has a fairly large temperature coefficient of resistance, the resistance of the inductor and the current through the inductor should make a DC voltage less than 110 mV when the inductor is at the maximum temperature for the converter. This also applies for the external resistor in Figure 19. The full load output current multiplied by the sense resistor value, must be less that 110 mV at the maximum converter operating temperature.

There is also a constraint on the negative (reverse current) voltage that can be applied to the ISNS pins of the TPS40400. The voltage differential from ISNS+ to ISNS- should not be less than -45 mV. If this condition is not met, inaccurate results from the READ_IOUT command is the result. This is intended to be a ripple voltage limitation. The net current through the inductor must flow towards the load from the input voltage. Current sinking, while possible for the controller to accommodate, is not supported for overcurrent detection or for the READ_IOUT command.

In all cases, C4 should be placed as close to the ISNS pins as possible to help avoid problems with noise.

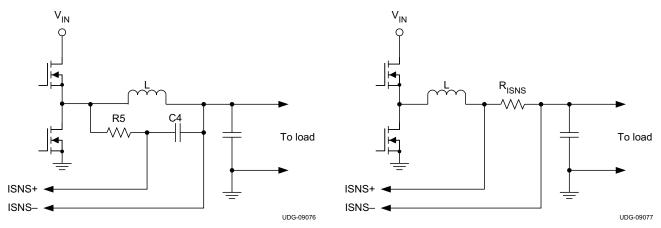


Figure 18. Current Sensing Using Inductor Resistance

Figure 19. Current Sensing Using Sense Resistor

Once the current sensing method is chosen, the TPS40400 needs to be told what the resistance of the current sense element is. This allows the proper calculation of thresholds for the overcurrent fault and warning, as well as more accurate reporting of the actual output current. The IOUT_CAL_GAIN command is used to set the value of the sense element resistence of the device. IOUT_OC_WARN_LIMIT and IOUT_OC_FAULT_LIMIT set the levels for the overcurrent warning and fault levels respectively. (See the PMBus Functionality and Additional Setup section for more details.)

Linear regulators. The TPS40400 has two on board linear regulators primarily intended to provide suitable power for the internal circuitry of the device. These pins, BP3 and BP6 must be properly bypassed to function properly. BP3 needs a minimum of 100nF connected to GND and BP6 should have approximately 1μ F connected to GND.

It is permissible to use the external regulator to power other circuits if desired, but care must be taken to ensure that the loads placed on the regulators do not adversely affect operation of the controller. The main consideration is to avoid loads with heavy transient currents that can affect the regulator outputs. Transient voltages on these outputs could result in noisy or erratic operation of the TPS40400.

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address on the bus. The TPS40400 has 64 possible addresses (0 through 63 in decimal) that can be assigned by connecting resistors from the ADDR0 and ADDR1 pins to SGND. The address is set in the form of two octal (0-7) digits, one digit for each pin. ADDR1 is the high-order digit and ADDR0 is the low-order digit.

The E96 series resistors suggested for each digit value are shown in Table 1.

The TPS40400 also detects values that are out of range on the ADDR0 and ADDR1 pins. If either pin is detected as having an out of range resistance connected to it, the TPS40400 continues to respond to PMBus commands, but at address 127, which is outside of the possible programmed addresses. It is possible but not recommended to use the device in this condition, especially if other TPS40400 devices are present on the bus or if another device could possibly occupy the 127 address.

PMBus connections. The TPS40400 supports both the 100 kHz and 400 kHz bus speeds. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400-kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, smbus.org.

PMBus Functionality and Additional Setup

Data format. There are three data formats supported in PMBus form commands that require representation of a literal number as their argument (commands that set thresholds, voltages or report such). A compatible device needs to only support one of these formats. The TPS40400 supports the Linear data format only for these commands. In this format, the data argument consists of two parts, a mantissa and an exponent. The number represented by this argument can be expressed as shown in Equation 5.

Value = Mantissa × 2^{exponent}

(5)

DIGIT	RESISTANCE (k Ω)
0	10
1	15.4
2	23.7
3	36.5
4	54.9
5	84.5
6	130
7	200

Table 1 E96 Series Resistors

Current limits must also be observed. Shorting the BP3 pin to GND damages the BP3 regulator. The BP3 regulator input comes from the BP6 regulator output. The current limit circuit on the BP6 regulator is 100 mA so the total current drawn from both regulators must be less than that. This total current includes the TPS40400 operating current IVDD plus the gate drive current required to drive the power FETs. The total available current from two regulators is found in Equation 3 and Equation 4:

$$I_{\text{LIN}} = I_{\text{BP6}} - (I_{\text{VDD}} + I_{\text{GATE}})$$

$$I_{GATE} = f_{SW} \times \left(Q_{gHIGH} + Q_{gLOW} \right)$$

where

- ILIN is the total current that can be drawn from BP3 and BP6 in aggregate
- I_{BP6} is the current limit of the BP6 regulator 100 mA minimum
- IVDD is the quiescent current of the TPS40400 15 mA maximum
- IGATE is the gate drive current required by the power FETs
- f_{SW} is the switching frequency
- Q_{aHIGH} is the total gate charge required by the high-side FET
- Q_{qLOW} is the total gate charge required by the low-side FET

(4) PMBus address. The PMBus specification requires that each device connected to the PMBus have a unique

(3)







Output voltage adjustment. The nominal output voltage of the converter can be adjusted using the VOUT_TRIM command. See the VOUT_TRIM command description for the format of this command as used in the TPS40400. The adjustment range is ±25% from the nominal output voltage. The VOUT_TRIM command is typically used to trim the final output voltage of the converter without relying on high precision resistors being used in Figure 17. The resolution of the adjustment is 7 bits, with a resulting minimum step size of approximately 0.4%. Note that the output margining is accomplished using this same 7 bit structure so the total combined deviation from the nominal output for margining and VOUT_TRIM is still limited to ±25%. Exceeding this range causes errors.

In order for the PMBus output voltage adjustments to function correctly, the VOUT_SCALE_LOOP parameter must be set properly. VOUT_SCALE_LOOP is a PMBus command (*see Supported PMBus Commands*) that tells the controller what the ratio of the voltage divider that sets the nominal output voltage is. The data for this command is the ratio of the divider that is used to set the output voltage. From Figure 17, VOUT_SCALE_LOOP parameter can be calculated using Equation 6.

$$VOUT_SCALE_LOOP = \frac{V_{FB}}{V_{OUT(nom)}}$$

(6)

(7)

The resolution of the VOUT_SCALE_LOOP command is 0.00195, or slightly under 0.2% due to the data format of the command (the linear data mode exponent is fixed at -9 for this command). This granularity affects the accuracy of adjustments to the output voltage made using the PMBus (VOUT_TRIM, VOUT_MARGIN_HIGH and VOUT_MARGIN_LOW) as well as setting the over and under voltage fault and warning levels. These commands use the VOUT_SCALE_LOOP parameter to calculate what the reference voltage needs to be for the requested output voltage or the thresholds referenced to the FB pin need to be for the requested warning and fault levels.

Once the VOUT_SCALE_LOOP parameter has been properly set, the commands that adjust the output voltage functions properly. There are three possible states that the TPS4040 can be in when considering what the actual output voltage is:

- No output margin
- Margin high
- Margin low

These output states are set using the OPERATION command. The FB pin reference voltage is calculated as follows in each of these states.

No margin voltage:

$$V_{FB} = ((VOUT_TRIM \times VOUT_SCALE_LOOP) + 0.6)$$

Margin high voltage state:

$$V_{FB} = ((VOUT_MARGIN_HIGH + VOUT_TRIM) \times VOUT_SCALE_LOOP)$$
(8)

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Margin low state:

where

- V_{FB} is the FB pin voltage
- VOUT_TRIM is the offset voltage in volts to be applied to the output voltage
- VOUT_SCALE_LOOP is the output voltage divider scale parameter
- VOUT_MARGIN_HIGH is the requested margin high voltage
- VOUT_MARGIN_LOW is the requested margin low voltage

For these conditions, the output voltage is shown in Equation 10.

$$V_{OUT} = V_{FB} \times \left(\frac{(R2 + R1)}{R2}\right)$$

where

- V_{FB} is the pin voltage calculated in Equation 7
- R2 and R1 are in consistent units from Figure 17
- VOUT is the output voltage

(10)

(9)

NOTE

The sum of the margin and trim voltages cannot be more that $\pm 25\%$ from the nominal output voltage. The FB pin voltage can deviate no more that this from the nominal 600 mV.

When using the margin commands, the transition rate between any two of the three states (margin high, no margin and margin low) is determined by the soft start time (set by TON_RISE and the output voltage information available to the controller using the VOUT_SCALE_LOOP command. The result is that the transition rate between margin states is the same volts per second as the soft start ramp – assuming that the user has input the correct value for VOUT_SCALE_LOOP.

Overcurrent thresholds. PMBus provides for adjustable overcurrent in the TPS40400. To function properly, the TPS40400 must be given the current sensing element resistance value. This is accomplished by issuing the IOUT_CAL_GAIN command with the argument set to the resistance of the sense element (see the IOUT_CAL_GAIN command description). The resolution of this command is 30.5 $\mu\Omega$ and the range is 0 to 15.6 m Ω .

Another command, IOUT_CAL_OFFSET (see the command description) can be used to trim out offset errors in the READ_IOUT command results, overcurrent warning and fault level thresholds. The resolution of this command is 62.5 mA Offsets cannot be trimmed closer than half of this amount. The range for this command is -4 A to 3.937 A. Calibrating offsets to a level greater than this is not possible.

Once these two parameters have been set the IOUT_OC_WARN_LIMIT and IOUT_OC_FAULT_LIMIT limit commands can be used to set the overcurrent warning and fault thresholds for the converter. There are two resolution limiting factors in setting the overcurrent thresholds. The first is the resolution available in the IOUT_OC_WARN_LIMIT and IOUT_OC_FAULT_LIMIT commands. The resolution available here is 500 mA. This is the absolute minimum adjustment that can be made to these thresholds. The other potential limit is the resolution of the overcurrent DAC and can result in lower resolution. The overcurrent detection is done using a DAC to set the threshold and a comparator to sense when the actual current level is above that threshold. The resolution of the DAC is 1.875 mV. The resistance of the current sense element and this resolution determine the minimum adjustment that can be made to the overcurrent warning and fault thresholds. That minimum adjustment is given in Equation 11.

$$I_{\Delta OC} = \frac{1.875 \text{mV}}{R_{\text{ISNS}}}$$

where

 $I_{\Delta OC}$ is the minimum change that can be made in the overcurrent warning or fault threshold



R_{ISNS} is the resistance of the current sensing element, either the inductor DC resistance or the resistance of the current sense resistor used (11)

Combining these two resolution limits shows that for current sense elements with a resistance below 3.75 m Ω , the overcurrent resolution is given by Equation 11. For current sense element resistances above 3.75 m Ω , the overcurrent warning and fault resolution is 500 mA.

The TPS40400 has built in temperature correction for the temperature coefficient of resistance for copper wound inductors used as current sense elements. As the temperature of a copper wound inductor increases, its resistance increases, resulting in a higher DC component of voltage across it for a given current. This leads to a decrease in the current that would actually trip the overcurrent thresholds. The voltages that the TPS40400 uses to represent the overcurrent thresholds is automatically adjusted higher as the die temperature of the TPS40400 increases. The temperature coefficient for the increase of the thresholds is chosen close to the temperature coefficient of copper at 4000 ppm/°C. The change in overcurrent threshold voltage from one temperature to another is given in Equation 12.

$$V_{OC2} - V_{OC1} = (T2 - T1) \times (1 + TC_{CU}) \times V_{OC1}$$

where

- V_{OC1} and V_{OC2} are the overcurrent threshold voltages
- T1 and T2 are the corresponding temperatures in °C
- T_{CCU} is the temperature coefficient, 0.004

(12)

The change in overcurrent threshold voltages given in Equation 12 maintains the actual overcurrent trip points near constant only if the die temperature of the TPS40400 and the copper temperature of the inductor are closely coupled. If the inductor copper temperature rises higher than the TPS40400 die temperature, the overcurrent thresholds appears to decrease and vice versa.

Temperature compensation applied to the overcurrent thresholds must be considered. The threshold voltage must not be or become greater (with the internal temperature compensation) than 110 mV referred to the voltage at the ISNS pins. For instance, if a 10 m Ω resistance inductor was used as the current sense element, a current of 10 A would cause a 100mV DC level at the current sense pins. At first this looks just fine and within the bounds of the 110 mV limit of the controller. However, the temperature compensation of the threshold inside the device raises the effective threshold as the TPS40100 die temperature increases. For 100°C increase in die temperature, for example, the effective threshold crossed at the ISNS pins to trip an overcurrent is approximately 140 mV at the ISNS pins. The TPS40400 cannot respond this high and the result is a failure of the overcurrent mechanism to respond at higher die temperatures. For a given maximum temperature defined by the characteristics of the particular application, the maximum overcurrent setting that should be made for the TPS40400 is calculated in Equation 13.

$$I_{MAX} = \frac{V_{ISNS}(max)}{R_{ISNS} \times ((T_{MAX} - 25) \times (TC_{CU} + 1))}$$

where

- I_{MAX} is the maximum overcurrent threshold setting permissible (using the IOUT_OC_FAULT_LIMIT command) in A
- V_{ISNS(max)} is the maximum allowable voltage differential at the ISNS pins, 120 mV R_{ISNS} is the resistance of the current sensing element – either inductor or current sense resistor
- T_{MAX} is the maximum junction temperature expected for the TPS40400 in °C
- TC_{CU} is the temperature coefficient of resistance for copper, 0.004

(13)

Equation 13 is illustrated in Figure 20. This figure shows the variation of the internal overcurrent threshold as the die temperature increases. In this example, the designated maximum die temperature is 125°C. For the overcurrent threshold to be valid at this temperature (110 mV or below), the maximum overcurrent threshold that should be set using the IOUT_OC_FAULT or IOUT_OC_WARN commands should correspond to no more than 75.7 mV. The current level that achieves this is what is calculated in Equation 13. If the maximum expected die temperature is less than 125°C, then the maximum 25°C overcurrent threshold increases accordingly.



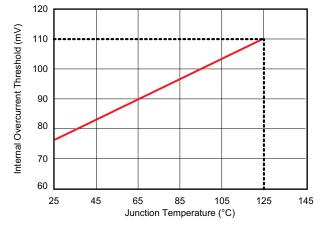


Figure 20. Internal Overcurrent Threshold Variation

Reading the output current. The average output current for the converter is readable using the READ_IOUT command. The results of this command support only positive or current sourced from the converter. If the converter is sinking current the result of this command is a reading of 0 A. Another consideration is the amount of ripple voltage applied to the ISNS pins when the DC voltage level is low – i.e., low or no output current. Because the TPS40400 averages out the ripple voltage when reporting the output current using the READ_IOUT command. Excessive negative ripple voltage ($V_{ISNS+} - V_{ISNS-} < 0$) at the ISNS pins causes an error in the reported output current. To ensure accurate readings the differential voltage at these pins should not be allowed to exceed –45 mV.

Soft-start time. The TPS40400 supports several soft-start times from 600 µs to 9 ms selected by the TON_RISE PMBus command. See the command description for full details on the levels and implementation. When selecting the soft-start time, care must be taken to ensure that the charging current for the output capacitors is considered. In some applications (e.g., those with large amounts of output capacitance) this current can lead to problems with nuisance tripping of the overcurrent protection circuitry. To ensure that this does not happen, the output capacitor charging current should be included when considering where to set the overcurrent threshold. The output capacitor charging current can be found using Equation 14:

$$I_{CAP} = \frac{V_{OUT} \times C_{OUT}}{t_{SS}}$$

where

- I_{CAP} is the startup charging current of the output capacitance in A
- V_{OUT} is the output voltage of the converter in V
- C_{OUT} is the total output capacitance in F
- t_{SS} is the selected soft-start time in seconds

(14)

With the charging current calculated, the overcurrent threshold can then be calibrated to the sum of the maximum load current and the output capacitor charging current plus some margin. The amount of margin required depends on the individual application, but 25% is a suggested starting point. More or less may be required.

Power good. The TPS40400 has user selectable power good thresholds. These thresholds determine at what voltage the PGOOD pin is allowed to go high and the associated PMBus flags are cleared. There are three possible settings that can be had. See the POWER_GOOD_ON and POWER_GOOD_OFF command descriptions for complete details. Note that these commands establish symmetrical values above and below the nominal voltage. Values entered for each threshold should be the voltages corresponding to the threshold below the nominal output voltage. For instance, if the nominal output voltage is 3.3 V, and the desired power good on thresholds are ±5%, the POWER_GOOD_ON command is issued with 2.85 V as the desired threshold. The POWER_GOOD_OFF command must be set to a lower value (higher percentage) than the POWER_GOOD_ON command as well. The VOUT_SCALE_LOOP command must be set to approximately 0.1818 for these examples to work correctly.



The FB pin is used to sense the output voltage for the purposes of power good detection. Because of this there is the inherent filtering action provided by the compensation network connected from COMP to FB. As the output voltage rises or falls below the nominal value, the error amplifier attempts to force FB to match its reference voltage. When the error amplifier is no longer able to do this, the FB pin begins to drift and trip the power good threshold. For this reason the network from COMP to FB should have no purely resistive path.

Power good de-asserts during all startups, after any fault condition is detected or whenever the device is turned off or in a disabled state (OPERATION command or CNTL pin put the device into a disabled or off state). The PGOOD pin acts like a diode to GND when the device has no power applied to the VDD pin.

Undervoltage lockout. The TPS40400 provides flexible user adjustment of the undervoltage lockout threshold and the hysteresis. Two PMBus commands VIN_ON and VIN_OFF allow the user to set these input voltage turn on and turn off thresholds independently, with a 500-mV resolution from a minimum of 2.5-V turn off to a maximum 18-V turn on. See the command descriptions for more details.

Output overvoltage and undervoltage thresholds. The TPS40400 has output overvoltage protection and undervoltage protection capability. The comparators that look at the overvoltage conditions and undervoltage conditions use the FB pin as the output sensing point so the filtering effect of the compensation network connected from COMP to FB has an effect on the speed of detection. As the output voltage rises or falls below the nominal value, the error amplifier attempts to force FB to match its reference voltage. When the error amplifier is no longer able to do this, the FB pin begins to drift and trip the overvoltage threshold or the undervoltage threshold. For this reason the network from COMP to FB should have no purely resistive path.

The VOUT_OV_FAULT_LIMIT and VOUT_UV_FAULT_LIMIT commands are used to set the output overvoltage and undervoltage thresholds. There are four possible thresholds that can be set with the undervoltage and overvoltage commands. See the command descriptions for complete details.

Programmable fault responses. For the various fault conditions, the TPS40400 allows the user to select the fault response. The faults that have programmable responses with the TPS40400 are overcurrent (see the IOUT_OC_FAULT_RESPONSE command description), overtemperature, (see the OT_FAULT_RESPONSE command description), output overvoltage, (see the VOUT_OV_FAULT_RESPONSE command description) and output undervoltage, (see the VOUT_UV_FAULT_RESPONSE command description). These commands program the TPS40400 response to the corresponding fault condition. Possible responses include ignoring the fault, latching off and requiring a reset (either VDD power cycle or a toggling of the CNTL pin and/or OPERATION command status) for the converter to restart. See the individual fault response command descriptions for details on what is available for the specific command.

User data and adjustable anti-cross conduction delay. The TPS 40400 provides a command, MFR_SPECIFIC_00, which can be used as a scratchpad to store 14 bits of arbitrary data. These bits can represent anything that the user desires and can be stored in EEPROM for non-volatility. Bit 0 of this command is used to select between two dead time settings for the controller. The particular setting required for a given application depends upon several things, including total FET gate charge, FET gate resistance, PCB layout quality, temperature, etc. It is not possible to give a hard and fast rule as to when to use which setting, but generally, for FETs above 25 nC gate charge, the longer dead time setting should be looked at. The shorter dead time setting allows higher efficiency in applications where the FETs are generally small and switch very quickly, while may lead to minimum amounts of cross conduction in applications with larger, slower switching FETs. Conversely, using the longer dead time setting with smaller, faster switching FETs leads to excessive body diode conduction in the low-side FET, leading to a drop in converter efficiency. Bit 1 of this command permanently locks certain parameters from being changed when set to 1. Use with caution. For more detail, see the MFR_SPECIFIC_00 command description.

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SUPPORTED COMMANDS

The TPS40400 supports the following commands from the PMBus 1.1 specification.

OPERATION (01h)

The OPERATION command is used to turn the device output on or off in conjunction with the input from the CONTROL pin. It is also used to set the output voltage to the upper or lower MARGIN voltages. The unit stays in the commanded operating mode until a subsequent OPERATION command or a change in the state of the CONTROL pin instructs the device to change to another mode.

Command				OPER	ATION			
Format				Unsigne	d binary			
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r	r/w	r/w	r/w	r/w	r	r
Function	ON	Х		Ма	rgin		Х	Х
Default Value	0	0	0	0	0	0	Х	Х

On

This bit is an enable command to the converter.

- 0: output switching is disabled. Both drivers placed in an off or low state.
- 1: output switching is enabled. The device is allowed to begin power conversion assuming no fault conditions exist.

Margin

If Margin Low is enabled, load the value from the VOUT_MARGIN_LOW command. If Margin High is enabled, load the value from the VOUT_MARGIN_HIGH command. (See PMBus specification for more information)

- 00XX: Margin Off
- 0101: Margin Low (Ignore Fault)
- 0110: Margin Low (Act on Fault)
- 1001: Margin High (Ignore Fault)
- 1010: Margin High (Act on Fault)

Note that the reference voltage used for overvoltage, undervoltage detection and power good are derived from the actual reference voltage in effect at the time. Setting a margin to test for one of these fault conditions does not work. Testing for these conditions must be done by forcing the FB pin to a voltage that would trip these fault conditions based on the current reference voltage and the percentage difference from this level set by the threshold setting commands.

ON_OFF_CONFIG (02h)

The ON_OFF_CONFIG command configures the combination of CNTL pin input and serial bus commands needed to turn the unit on and off. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command				ON_OFF	CONFIG			
Format				Unsigne	d binary			
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r/w	r/w	r/w	r/w	r
Function	Х	Х	Х	pu	cmd	cpr	pol	сра
Default Value	Х	Х	Х	1	0	1	1	1

ри

The pu bit sets the default to either operate any time power is present or for the on/off to be controlled by CNTL pin and PMBus OPERATION command. This bit is used in conjunction with the 'cp', 'cmd', and 'on' bits to determine start up.



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Bit Value	ACTION
0	Device powers up any time power is present regardless of state of the CNTL pin.
1	Device does not power up until commanded by the CNTL pin and OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

cmd

The cmd bit controls how the device responds to the OPERATION command.

Bit Value	ACTION
0	Device ignores the "on" bit in the OPERATION command.
1	Device responds to the "on" bit in the OPERATION command.

cpr

The cpr bit sets the CNTL pin response. This bit is used in conjunction with the 'cmd', 'pu', and 'on' bits to determine start up.

Bit Value	ACTION
0	Device ignores the CNTL pin. On/off is controlled only by the OPERATION command.
1	Device requires the CNTL pin to be asserted to start the unit.

pol

The pol bit controls the polarity of the CONTROL pin. For a change to become effective, the contents of the ON_OFF_CONFIG register must be stored to non-volatile memory using either the SOR_DEFAULT_ALL or STORE_DEFAULT_CODE commands and the device power cycled. Simply writing a new value to this bit does not change the polarity of the CNTL pin.

Bit Value	ACTION
0	CNTL pin is active low.
1	CNTL pin is active high.

сра

The cpa bit sets the CNTL pin action when turning the controller off. This bit is read internally and cannot be modified by the user.

Bit Value	ACTION
1	Turn off the output and stop transferring energy to the output as fast as possible.

CLEAR_FAULTS (03h)

The CLEAR_FAULTS command is used to clear any fault bits that have been set. This command clears all bits in all status registers simultaneously. At the same time, the device negates (clears, releases) its SMBALERT signal output if the device is asserting the SMBALERT signal. The CLEAR_FAULTS command does not cause a unit that has latched off for a fault condition to restart. If the fault is still present when the bit is cleared, the fault bit is immediately reset and the host notified by the usual means.

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WRITE_PROTECT (10h)

The WRITE_PROTECT command is used to control writing to the PMBus device. The intent of this command is to provide protection against accidental changes. This command is not intended to provide protection against deliberate or malicious changes to the device configuration or operation. All supported command parameters may have their parameters read, regardless of the WRITE_PROTECT settings. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command				WRITE_F	ROTECT			
Format	Unsigned binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	Х	Х	Х	Х	Х
Function	bit7	bit6	bit5	Х	Х	Х	Х	Х
Default Value	0	0	0	Х	Х	Х	х	Х

bit5

Bit Value	ACTION
0	Enable all writes as permitted in bit6 or bit7
1	Disable all writes except the WRITE_PROTECT, OPERATION and ON_OFF_CONFIG. (bit6 and bit7 must be 0 to be valid data)

bit6

Bit Value	ACTION
0	Enable all writes as permitted in bit5 or bit7
1	Disable all writes except for the WRITE_PROTECT and OPERATION commands. (bit5 and bit7 must be 0 to be valid data)

bit7

Bit Value	ACTION
0	Enable all writes as permitted in bit5 or bit6
1	Disable all writes except for the WRITE_PROTECT command. (bit5 and bit6 must be 0 to be valid data)

In any case, only one of the three bits may be set at any one time. Attempting to set more than one bit results in an alert being generated and the cml bit is STATUS_WORD being set.

STORE_DEFAULT_ALL (11h)

The STORE_DEFAULT_ALL command stores all of the current storable register settings in the EEPROM memory as the new defaults on power up.

It is permissible to use this command while the device is switching. Note however that the device continues to switch but ignores all fault conditions until the internal store process has completed.

EEPROM programming faults cause the device to NACK and set the 'cml' bit in the STATUS_BYTE and the 'oth' bit in the STATUS_CML registers.

RESTORE_DEFAULT_ALL (12h)

The RESTORE_DEFAULT_ALL command restores all of the storable register settings from EEPROM memory.

This command should not be used while the device is actively switching. If this is done, the device stops switching the output drivers and the output voltage drops. Depending on loading conditions, the output voltage could reach an undervoltage level and trigger an undervoltage fault response if programmed to do so. The command can be used while the device is switching, but it is not recommended as it results in a restart that could disrupt power sequencing requirements in more complex systems. It is strongly recommended that the device be stopped before issuing this command.



STORE_DEFAULT_CODE (13h)

The STORE_DEFAULT_CODE command instructs the PMBus core to store the contents of the programming register whose Command Code matches the value in the data byte into memory as the new default value.

Command		STORE_DEFAULT_CODE									
Bit Position	7	6	5	4	3	2	1	0			
Access	w	w	w	w	w	w	w	w			
Function	Command code										

EEPROM programming faults cause the device to NACK and set the 'cml' bit in the STATUS_BYTE and the 'oth' bit in the STATUS_CML registers. It is permissible to use this command while the device is switching. Note however that the device continues to switch but ignores all fault conditions until the internal store process has completed.

It is permitted to use the STORE_DEFAULT_CODE command while the device is operating. However, the device may be unresponsive during the copy operation with unpredictable, undesirable or even catastrophic results. It is recommended to turn off the device output before issuing this command.

RESTORE_DEFAULT_CODE (14h)

The RESTORE_DEFAULT_CODE command instructs the PMBus core to overwrite the programming register whose Command Code matches the value in the data byte, with the default value.

Command		STORE_DEFAULT_CODE									
Bit Position	7	6	5	4	3	2	1	0			
Access	w	w	w	w	w	w	w	w			
Function	Command code										

The RESTORE_DEFAULT_CODE command should not be used while the device is switching because the device stops switching and restarts. During the restart, the low-side driver turns on for an extended time period and could damage loads that are sensitive to the power rail sinking current. If this is of no concern then the command may be used while the device is switching.

NOTE

VIN UV triggered when RESTORE DEFAULT ALL А fault may be or RESTORE_DEFAULT_CODE command is set. The firmware workaround is accomplished upon completion of a RESTORE_DEFAULT_ALL by verifying that, or RESTORE_DEFAULT_CODE command, the sole source asserting SMB_ALERT is STATUS_BYTE[3] (VIN_UV). If so, issue a CLEAR_FAULTS command. Any other source asserting SMB_ALERT under these circumstances (i.e. completion of RESTORE DEFAULT ALL or RESTORE_DEFAULT_CODE) would indicate an actual fault condition.

VOUT_MODE (20h)

Description: The PMBus specification dictates that the data word for the VOUT_MODE command is one byte that consists of a 3-bit mode and 5-bit exponent parameter, as shown below. The 3-bit mode sets whether the device uses the Linear or Direct modes for output voltage related commands. The 5-bit parameter sets the exponent value for the linear data mode. The mode and exponent parameters are set and do not permit the user to change the values.

Command				VOUT_	MODE				
Bit Position	7	6	5	4	3	2	1	0	
Access	r	r r r r r r							
Function		Mode Exponent							
Default Value	0	0	0	1	0	1	1	0	

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Mode:

Value fixed at 000, linear mode.

Exponent

Value fixed at 11011, Exponent for Linear mode values is -10.

VOUT_TRIM (22h)

The VOUT_TRIM command is used to apply a fixed offset voltage to the output voltage command value. It is most typically use by the end user to trim the output voltage at the time the PMBus device is assembled into the end user system. It is vital that the VOUT_SCALE_LOOP command is set correctly in order to obtaining correct results. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The effect of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of –10 (decimal).

 $V_{OUT(offst)} = VOUT_TRIM \times 2^{-10}$

The maximum value of V_{OUT(offst)} is ±25% of nominal VOUT. Nominal V_{OUT} is set by external resistors and the 600 mV error amplifier reference. The valid range in 2s complement for this command is –4000h to 3FFF. The high order two bits of the high byte must both be either 0 or 1. They cannot have different values. If a value outside of the ±25% is given with this command, the TPS40400 sets the output voltage to the upper or lower limit depending on the direction of the setting, assert SMBALRT, set the CML bit in STATUS_BYTE and the invalid data bit STATUS_CML.

Command								VOUT	TRIM							
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r/w	v r r/w r/w r/w r/w r/w r/w r/w r/w r/w r														
Function				High	Byte							Low	Byte			
Default Value	0 0 0 0 0 0 0								0	0	0	0	0	0	0	0

VOUT_MARGIN_HIGH (25h)

The VOUT_MARGIN_HIGH command sets the target voltage which the output changes to when the OPERATION command is set to "Margin High". The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The effect of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal). The actual output voltage commanded by a margin high command can be found by:

$$V_{OUT(MH)} = (VOUT_MARGIN_HIGH + VOUT_TRIM) \times 2^{-10}$$

(16)

The maximum margin range is ±25% of nominal VOUT. Nominal VOUT is set by external resistors and a 600 mV error amplifier reference and does not include the offset generated by VOUT_TRIM. It is critical that the correct value be programmed into VOUT_SCALE_LOOP for the correct margin value to be calculated. Error checking is not performed when the VOUT_MARGIN_HIGH command is issued. The error checking is done when the OPERATION command is issued calling for a margin high state. At that time, values outside the ±25% range is treated as invalid data and causes the set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers. The output voltage is then set to to the upper or lower limit depending on the direction of the setting. The device state can be restored to power up defaults by issuing either the RESTORE_DEFAULT_ALL or RESTORE_DEFAULT_CODE commands.



(15)



Command		VOUT_MARGIN_HIGH														
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		High Byte Low Byte														
Default Value	0	0 0 0 0 1 0 1 0 1 0 0 0 0 1 1														

The default value of VOUT_MARGIN_HIGH is 0x547 or 1351. This corresponds to a default margin high voltage of 1.32 V with the default VOUT_SCALE_LOOP value of 0.5 and external resistor selection to give 1.2 V nominal output voltage.

VOUT_MARGIN_LOW (26h)

The VOUT_MARGIN_LOW command sets the target voltage which the output changes to when the OPERATION command is set to "Margin Low". The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The effect of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal). The actual output voltage commanded by a margin high command can be found by:

$$V_{OUT(ML)} = (VOUT_MARGIN_LOW + VOUT_TRIM) \times 2^{-10}$$

(17)

The maximum margin range is ±25% of nominal VOUT. Nominal VOUT is set by external resistors and a 600 mV error amplifier reference and does not include the offset generated by VOUT_TRIM. It is critical that the correct value be programmed into VOUT_SCALE_LOOP for the correct margin value to be calculated. Error checking is not performed when the VOUT_MARGIN_LOW command is issued. The error checking is done when the OPERATION command is issued calling for a margin high state. At that time, values outside the ±25% range is treated as invalid data and causes the device to set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers. The output voltage is then set to the upper or lower limit depending on the direction of the setting. The device state can be restored to power up defaults by issuing either the RESTORE_DEFAULT_ALL or RESTORE_DEFAULT_CODE commands.

Command		VOUT_MARGIN_LOW														
Format		Linear, two's complement binary														
Bit Position	7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		High Byte Low Byte														
Default Value	0	0	0 0 0 0 1 0 0 1 0 1 0 1 0 1													

The default value of VOUT_MARGIN_LOW is 0x451 or 1105. This corresponds to a default margin high voltage of 1.08 V with the default VOUT_SCALE_LOOP value of 0.5 and external resistor selection to give 1.2 V nominal output voltage.

VOUT_SCALE_LOOP (29h)

VOUT_SCALE_LOOP is equal to the feedback resistor ratio. The nominal output voltage is set by a resistor divider and the internal 600mV reference voltage. The default value of VOUT_SCALE_LOOP is 0.5 meaning that the reference voltage is one half of the output voltage. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The correct setting for the VOUT_SCALE_LOOP parameter is shown in Equation 18.

$$VOUT_SCALE_LOOP = \frac{V_{FB}}{V_{OUT(nom)}}$$

(18)

It is important that this parameter is set correctly because it has an effect on several other parameters. Any parameter that operates on or reports output voltage depends on the correct setting of this parameter for correct results to be obtained.

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Command							vol	JT_SC	ALE_LO	DOP						
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		Exponent Mantissa														
Default Value	1	0 1 1 1 0 0 1 0 0 0 0 0 0 0 0														

Exponent

Value fixed at -9 (dec).

Mantissa

Default value is 256 (dec). When combined with the exponent, the overall value of VOUT_SCALE_LOOP is 0.5 (dec). The maximum value for the mantissa is 512 for a VOUT_SCALE_LOOP value of 1.

FREQUENCY_SWITCH (33h)

The FREQUENCY_SWITCH command sets the switching frequency. Smarty Jones only supports frequencies from 200 kHz to 2 MHz. Values written within the supported frequency range is rounded up to the nearest supported increment. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

There are 14 distinct supported frequencies:

- 200 kHz
- 300 kHz
- 400 kHz
- 500 kHz
- 600 kHz (default)
- 700 kHz
- 800 kHz
- 900 kHz
- 1.0 MHz
- 1.2 MHz
- 1.4 MHz
- 1.6 MHz
- 1.8 MHz
- 1.9 MHz

The data word that accompanies this command is divided into a fixed 5-bit exponent and an 11-bit mantissa. The 5 most significant bits of the mantissa are fixed, while the lower six bits may be altered.

Command		FREQUENCY_SWITCH														
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function		Exponent Mantissa														
Default Value	0	0 0 1 0 1 0 0 0 0 0 0 1 0 1 1														

Exponent

Fixed at 5(dec)

Mantissa

The upper five bits are fixed at 0.

The lower six bits are writeable with a default value of 19 (dec).



VIN_ON (35h)

The VIN_ON command sets the value of the input voltage at which the unit should start operation assuming all other required startup conditions are met. Values are mapped to the nearest supported increment. Values outside the supported range are treated as invalid data and cause the device set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers. The value of VIN_ON remains unchanged on an out-of-range write attempt. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

	SUPPORTED VIN	I_ON VALUES	
2.75 ⁽¹⁾	6.50	10.50	14.50
3.00	7.00	11.00	15.00
3.50	7.50	11.50	15.50
4.00	8.00	12.00	16.00
4.50	8.50	12.50	16.50
5.00	9.00	13.00	17.00
5.50	9.50	13.50	17.50
6.00	10.00	14.00	18.00

(1) Default setting

VIN_ON must be set higher than VIN_OFF. Attempting to write either VIN_ON lower than VIN_OFF or VIN_OFF higher than VIN_ON results in the new value being rejected, SMBALERT being asserted along with the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

The data word that accompanies this command is divided into a fixed 5-bit exponent and an 11-bit mantissa. The four most significant bits of the mantissa are fixed, while the lower 7 bits may be altered.

Command								VIN	ON							
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		E	Exponer	nt						I	Mantiss	a				
Default Value	1	1 1 1 0 0 0 0 0 0 1 0 1 1														

Exponent

-2 (dec), fixed.

Mantissa

The upper four bits are fixed at 0. The lower seven bits are programmable with a default value of 11 (dec).

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VIN_OFF (36h)

The VIN_OFF command sets the value of the input voltage at which the unit should stop operation. Values are mapped to the nearest supported increment. Values outside the supported range is treated as invalid data and causes the device to set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers. The value of VIN_ON remains unchanged during an out-of-range write attempt. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

	SUPPORTED VI	N_OFF VALUES	
2.50 ⁽¹⁾	6.50	10.50	14.50
3.00	7.00	11.00	15.00
3.50	7.50	11.50	15.50
4.00	8.00	12.00	16.00
4.50	8.50	12.50	16.50
5.00	9.00	13.00	17.00
5.50	9.50	13.50	17.50
6.00	10.00	14.00	

(1) Default setting

VIN_ON must be set higher than VIN_OFF. Attempting to write either VIN_ON lower than VIN_OFF or VIN_OFF higher than VIN_ON results in the new value being rejected, SMBALERT being asserted along with the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

The data word that accompanies this command is divided into a fixed 5 bit exponent and an 11 bit mantissa. The 4 most significant bits of the mantissa are fixed, while the lower 7 bits may be altered.

Command		VIN_OFF														
Format		Linear, two's complement binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1												0		
Access	r	r	r	r	r	r	r	r	r	r/w						
Function		E	Exponer	nt		Mantissa										
Default Value	1	1	1	1	0	0	0	0	0	0	0	0	1	0	1	0

Exponent

-2 (dec), fixed.

Mantissa

The upper four bits are fixed at 0. The lower seven bits are programmable with a default value of 10 (dec)

IOUT_CAL_GAIN (38h)

The IOUT_CAL_GAIN is the ratio of the voltage at the current sense element to the sensed current. The units are Ohms (Ω). The effective current sense element can be the DC resistance of the inductor or a separate current sense resistor. The default setting is 3 m Ω , and the resolution is 30.5 μ Ω . The range is 0 to 15.6 m Ω . The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		IOUT_CAL_GAIN														
Format		Linear, two's complement binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1												0		
Access	r	r	r	r	r	r	r	r/w								
Function		ĺ	Exponer	nt		Mantissa										
Default Value	1	0	0	0	1	0	0	0	0	1	1	0	0	0	1	0



Exponent

-15 (dec), fixed.

Mantissa

The upper four bits are fixed at 0. The lower seven bits are programmable with a default value of 98 (dec)

IOUT_CAL_OFFSET (39h)

The IOUT_CAL_OFFSET is used to compensate for offset errors in the READ_IOUT results and the IOUT_OC_FAULT_LIMIT and IOUT_OC_WARN_LIMIT thresholds. The units are amps. The default setting is 0 amps. The resolution of the argument for this command is 62.5 mA and the range is +3937.5mA to -4000 mA. Values written outside of this range alias into the supported range. For example, 1110 0100 0000 0001 has an expected value of -63.0625 amps, but results in 1110 0111 1111 0001 which is -0.9375 A. This occurs because the read-only bits are fixed. The Exponent is always -4 and the 5 msb bits of the Mantissa are always equal to the sign bit. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command							101	UT_CAI	OFFS	ΒET						
Format		Linear, two's complement binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1												0		
Access	r	r	r	r	r	r/w	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function		E	Exponer	nt		Mantissa										
Default Value	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0

Exponent

-4 (dec), fixed.

Mantissa

MSB is programmable with sign, next 4 bits are sign extend only. Lower six bits are programmable with a default value of 0 (dec)

VOUT_OV_FAULT_LIMIT (40h)

The VOUT_OV_FAULT_LIMIT command sets the value of the output voltage that causes an output overvoltage fault. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The effective value of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal) so the effective overvoltage trip point requested is:

$$V_{OUT(OV reg)} = VOUT_OV_FAULT_LIMIT \times 2^{-10}$$

(19)

The VOUT_OV_FAULT_LIMIT has two data bytes formatted as 2's complement binary integer. The actual values for the VOUT_OV_FAULT_LIMIT trip point are set to fixed percentages of nominal V_{OUT} . There are four fixed percentages of the nominal V_{OUT} that are supported for overvoltage trip points.

- 108%
- 110%
- 112% (default)
- 115%

For example, for a 1.2V nominal output, VOUT_OV_FAULT_LIMIT can be set to 1.296 V, 1.32 V, 1.344 V or 1.38 V. Values within the supported range is set to the nearest fixed percentage. It is critical that the correct value be programmed into VOUT_SCALE_LOOP for the correct overvoltage fault trip point to be calculated. Values outside the supported range results in the corresponding extreme value to be selected. No error conditions are reported

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Command							VOUT	[_OV_F	AULT_	LIMIT							
Format		Linear, two's complement binary															
Bit Position	7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0	
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
Function				High	Byte				Low Byte								
Default Value	0	0	0	0	0	1	0	1	0	0	0	0	1	0	0	0	

VOUT_OV_FAULT_RESPONSE (41h)

Description: The VOUT_OV_FAULT_RESPONSE command instructs the device on what action to take in response to a VOUT_OV_FAULT_LIMIT fault. The device also:

- Sets the VOUT_OV bit in the STATUS_BYTE
- Sets the VOUT bit in the STATUS_WORD
- Sets the VOUT OV fault bit in the STATUS_VOUT register, and
- Notifies the host via SMBALRT pin

The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

A one-byte unsigned binary data argument is used with this command:

Command			VC	OUT_OV_FAU	ILT_RESPON	SE		
Format				Unsigne	ed binary			
Bit Position	7	6	5	4	3	2	1	0
Access	r/W	r/w	r/w	r/w	r/w	r	r	r
Function	RSP[1]	RSP[0]	RS[2]	RS[1]	RS[0]	Х	Х	Х
Default Value	0	0	0	0	0	1	0	0

RSP[1:0]

Output voltage overvoltage response

- 00: The device continues operation without interruption.
- 01: The device continues operation for four switching cycles. If the fault is still present, the device shuts down and responds according to RS[2:0].
- 10: The device shuts down and responds according to RS[2:0].
- 11: The device shuts down and attempts to restart.

RS[2:0]

Output voltage overvoltage retry setting

- 000: A zero value for the Retry Setting means that the unit does not attempt to restart. The output remains disabled until the fault is cleared (See section 10.7 of the PMBus spec.)
- 111: A one value for the Retry Setting means that the unit goes through a normal startup (Soft start) continuously, without limitation, until it is commanded off or bias power is removed or another fault condition causes the unit to shutdown.

Any value other than 000 or 111 is not accepted.



VOUT_UV_FAULT_LIMIT (44h)

The VOUT_UV_FAULT_LIMIT command sets the value of the output voltage that causes an output undervoltage fault. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The effective value of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal) so the effective overvoltage trip point requested is:

(20)

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The VOUT_UV_FAULT_LIMIT has two data bytes formatted as two's complement binary integer. The actual values for VOUT_ UV_FAULT_LIMIT trip point are set to fixed percentages of nominal VOUT. There are four fixed percentages of V_{OUT} that are supported for overvoltage trip points.

- 92%
- 90%
- 88% (default)
- 85%

For example, for a 1.2 V nominal output, VOUT_UV_FAULT_LIMIT can be set to 1.104 V, 1.08 V, 1.056 V or 1.02 V. Values within the supported range are set to the nearest fixed percentage. It is critical that the correct value be programmed into VOUT_SCALE_LOOP for the correct overvoltage fault trip point to be calculated. Values outside the supported range results in the corresponding extreme value to be selected. No error conditions are reported.

The VOUT_UV_FAULT_LIMIT command has two bytes formatted as a two's compliment binary integer:

Command		VOUT_UV_FAULT_LIMIT															
Format		Linear, two's complement binary															
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0												0			
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
Function				High	Byte				Low Byte								
Default Value	0	0 0 0 0 0 1 0 0 1 0 1 0 0 1 1 1											1				

VOUT_UV_FAULT_RESPONSE (45h)

The VOUT_UV_FAULT_RESPONSE command instructs the device on what action to take in response to a VOUT_UV_FAULT_LIMIT fault. The device also:

- Sets the VOUT bit in the STATUS_WORD
- Sets the VOUT UV Fault bit in the STATUS_VOUT register, and
- Notifies the host via SMBALRT pin

The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

A one-byte unsigned binary data word is used with this command:

Command			VOU	L_UV_FAU	LT_RESP	ONSE		
Format				Unsigne	ed binary			
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r/w	r	r	r
Function	RSP[1]	RSP[0]	RS[2]	RS[1]	RS[0]	Х	Х	Х
Default Value	0	0	0	0	0	1	0	0

RSP[1:0]

Output voltage undervoltage response

00: The device continues operation without interruption.

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FXAS

- 01: The device continues operation for four switching cycles. If the fault is still present, the device shuts down and responds according to RS[2:0].
- 10: The device shuts down and responds according to RS[2:0].
- 11: The device shuts down and attempts to restart.

RS[2:0]

Output voltage undervoltage retry setting

- 000: A zero value for the Retry Setting means that the unit does not attempt to restart. The output remains disabled until the fault is cleared (See section 10.7 of the PMBus spec.)
- 111: A one value for the Retry Setting means that the unit goes through a normal startup (Soft start) continuously, without limitation, until it is commanded off or bias power is removed or another fault condition causes the unit to shutdown.

Any value other than 000 or 111 is not accepted.

IOUT_OC_FAULT_LIMIT (46h)

The IOUT_OC_FAULT_LIMIT command sets the value of the output current, in amperes, that causes the over-current detector to indicate an over-current fault condition. The IOUT_OC_FAULT_LIMIT should be set to equal to or greater than the IOUT_OC_WARN_LIMIT. Writing a value to IOUT_OC_FAULT_LIMIT less than IOUT_OC_WARN_LIMIT cause a the device to set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers as well as assert the SMBALRT signal. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The IOUT_OC_FAULT_LIMIT takes a two-byte data word formatted as follows:

Command		IOUT_OC_FAULT_LIMIT														
Format		Linear, two's complement binary														
Bit Position	7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function		I	Exponer	nt		Mantissa										
Default Value	1	1	1	1	1	0	0	0	0	0	0	1	0	1	0	0

Exponent

-1 (dec), fixed.

Mantissa

The upper five bits are fixed at 0.

The lower six bits are programmable with a default value of 20 (dec)

The actual output current for a give mantissa and exponent is shown in Equation 21.

$$OUT(oc) = Mantissa \times 2^{Exponent} = \frac{Mantissa}{2}$$

(21)

The default output fault current setting is 10 A. Values of I_{OUT(oc)} can range between 0 A and 35 A in 500-mA increments.

IOUT_OC_FAULT_RESPONSE (47h)

The IOUT_OC_FAULT_RESPONSE command instructs the device on what action to take in response to an IOUT_OC_FAULT_LIMIT fault. The device also:

- Sets the IOUT_OC bit in the STATUS_BYTE
- Sets the IOUT/POUT bit in the STATUS_WORD
- Sets the IOUT OC Fault bit in the STATUS_IOUT register, and
- Notifies the host as described in section 10.2.2 of the PMBus Specification.

The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		IOUT_OC_FAULT_RESPONSE											
Format		Unsigned binary											
Bit Position	7	7 6 5 4 3 2 1 0											
Access	r/w	r/w	r/w	r/w	r/w	r	r	r					
Function	RSP[1]	RSP[0]	RS[2]	RS[1]	RS[0]	Х	Х	Х					
Default Value	0	0	0	0	0	1	0	0					

RSP[1:0]

- 00: The device continues operation without interruption
- 01: This is unsupported and causes a data error.
- 10: The device continues operation for four switching cycles. If the fault is still present, the device shuts down and responds according to RS[2:0].
- 11: The device shuts down and attempts to restart.

RS[2:0]

- 000: A zero value for the Retry Setting means that the unit does not attempt to restart. The output remains disabled until the fault is cleared (See section 10.7 of the PMBus spec.)
- 111: A one value for the Retry Setting means that the unit goes through a normal startup (Soft start) continuously, without limitation, until it is commanded off or bias power is removed or another fault condition causes the unit to shutdown.

Any value other than 000 or 111 is not accepted.

IOUT_OC_WARN_LIMIT (4Ah)

The IOUT_OC_WARN_LIMIT command sets the value of the output current, in amperes, that causes the over-current detector to indicate an over-current warning. When this current level is exceeded the device:

- Sets the OTHER bit in the STATUS_BYTE
- Sets the OCW bit in the STATUS_WORD
- · Sets the IOUT overcurrent Warning (OCW) bit in the STATUS_IOUT register, and
- Notifies the host by asserting SMBALRT

The IOUT_OC_WARN_LIMIT threshold should always be set to less than or equal to the IOUT_OC_FAULT_LIMIT. Writing a value to IOUT_OC_WARN_LIMIT greater than IOUT_OC_FAULT_LIMIT causes the device to set the CML bit in the STATUS_BYTE and the invalid data (ivd) bit in the STATUS_CML registers as well as assert the SMBALRT signal. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The IOUT_OC_WARN_LIMIT takes a two byte data word formatted as follows:

Command		IOUT_OC_WARN_LIMIT														
Format		Linear, two's complement binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function		Exponent Mantissa														
Default Value	1	1	1	1	1	0	0	0	0	0	0	0	1	1	1	1

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Exponent

-1 (dec), fixed

Mantissa

The upper five bits are fixed at 0. Lower six bits are programmable with a default value of 15 (dec)

The actual output warning current level for a give mantissa and exponent is:

$$I_{OUT(oc)} = Mantissa \times 2^{Exponent} = \frac{Mantissa}{2}$$
 (22)

The default output fault current setting is 10A. Values of $I_{OUT(oc)}$ can range from 0A to 35A in 500mA increments. The default output warning current setting is 7.5A.

OT_FAULT_RESPONSE (50h)

The OT_FAULT_RESPONSE command instructs the device on what action to take in response to an output over temperature fault. The temperature sensed is the die temperature of the TPS40400 only. No other temperature sensors are provided. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands. The OT_FAULT_LIMIT parameter is not programmable and is therefore not supported in the PMBus command set. When an over temperature fault condition is sensed, the device:

- Sets the TEMPERATURE bit in the STATUS_BYTE
- Sets the OT FAULT bit in the STATUS_TEMPERATURE register, and
- Notifies the host by asserting the SMBALRT signal

A one-byte unsigned binary data word is used with this command:

Command		OT_FAULT_RESPONSE											
Format		Unsigned binary											
Bit Position	7	6	5	4	3	2	1	0					
Access	r	r/w	r	r	r	r	r	r					
Function	Х	OTF_RS	Х	Х	Х	Х	Х	Х					
Default Value	1	1	0	0	0	0	0	0					

OTF_RS

Over temperature fault retry setting

- 0: A zero value for the Retry setting indicates that the unit does not attempt to restart.
- 1: A one value for the Retry setting indicates that the unit goes through a normal startup (soft-start) when the die temperature falls below the hysteresis band limit. (See the *Electrical Characteristics* table).

POWER_GOOD_ON (5Eh)

The POWER_GOOD_ON command sets the value of the output voltage at which the PGOOD output pin (open drain) is asserted high. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands. The actual implementation is a window comparator with symmetrical thresholds above and below the nominal. This command sets both the upper and lower power good threshold at the same time. The parameter passed with this command is always the lower threshold (less than the nominal output) and is mapped to the closest supported percentages of the nominal output voltage inTable 2.



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Command Format

Bit Position

Default Value

Access

Function

The default value sets the power good turn on threshold to 1.1035V which maps to the 92% low threshold and 108% high threshold.

0

r/w

0

POWER GOOD OFF (5Fh)

7

r

0

6

r/w

0

5

r/w

0

4

r/w

0

3

r/w

0

High Byte

The POWER_GOOD_OFF command sets the value of the output voltage at which the PGOOD output pin (open drain output) is de-asserted low. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands. The actual implementation is a window comparator with symmetrical thresholds above and below the nominal. This command sets both the upper and lower power good threshold at the same time. The parameter passed with this command is always the lower threshold (less than the nominal output) and is mapped to the closest supported percentages of the nominal output voltage below:

For example, with a 1.2 V nominal output voltage, the POWER GOOD ON command can set the lower threshold to 1.14 V, 1.104 V or 1.08 V. Doing this automatically sets the upper thresholds to 1.26 V, 1.296 V and 1.32 V respectively.

The effective value of this command is determined by the settings of the VOUT MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal) so the effective lower power good turn on threshold requested is:

 $V_{OUT(PGOOD_ON)} = POWER_GOOD_ON \times 2^{-10}$

The nominal output voltage is set by external resistors and a 600-mV error amplifier reference. It is critical that the correct value be programmed into VOUT SCALE LOOP in order to correctly select the desired POWER_GOOD_ON threshold.

Normally, the POWER GOOD ON threshold is set higher than the POWER GOOD OFF threshold. If the POWER GOOD ON threshold is set to a value equal to or less than the POWER GOOD OFF threshold, the device:

- Sets the CML bit in the STATUS_BYTE
- Sets the Invalid data bit in STATUS CML
- Notifies the host via SMBALRT pin

It is the user's responsibility to ensure that the chosen POWER GOOD ON and POWER GOOD OFF thresholds are reasonable with respect to each other. For values written outside the supported ranges are ACK'ed but causes the SMBALRT line to assert and the CML bit to be set in the STATUS_WORD. The invalid data bit is also set in the STATUS CML results. The actual POWER GOOD ON threshold is set to the nearest supported extreme value. For instance, with VOUT_SCALE_LOOP set to 0.5 for a typical 1.2-V output supply, setting POWER_GOOD_ON to 0.5 results in the threshold being set to the 90% value.

POWER_GOOD_ON

Linear, two's complement binary

6

r/w

1

5

r/w

1

4

r/w

0

3

r/w

1

Low Byte

2

r/w

0

1

r/w

1

0

r/w

0

7

r/w

0

The POWER GOOD ON command has two data bytes formatted as two's complement binary integer:

1

r/w

0

2

r/w

1

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THRESHOLD									
Low	High								
95%	105%								
92%	108%								
90%	110%								

Table 2. Supported POWER GOOD ON Levels

(23)

Supported POWER_GOOD_OFF Levels										
Low Threshold High Threshold										
92%	108%									
90% ⁽¹⁾	110%									
88%	112%									

(1)	Default value
-----	---------------

For example, with a 1.2 V nominal output voltage, the POWER_GOOD_OFF command can set the lower threshold to 1.104 V, 1.0 8V or 1.056 V. Doing this automatically sets the upper thresholds to 1.296 V, 1.32 V and 1.344 V respectively.

The effective value of this command is determined by the settings of the VOUT_MODE command. In this device, the VOUT_MODE is fixed to Linear with an exponent of -10 (decimal) so the effective lower power good turn on threshold requested are:

 $V_{OUT(PGOOD_OFF)} = POWER_GOOD_OFF \times 2^{-10}$

(24)

The nominal output voltage is set by external resistors and a 600 mV error amplifier reference. It is critical that the correct value be programmed into VOUT_SCALE_LOOP for the correct POWER_GOOD_ON threshold to be selected.

Normally, the POWER_GOOD_ON threshold is set higher than the POWER_GOOD_OFF threshold. If the POWER_GOOD_ON threshold is set to a value equal to or less than the POWER_GOOD_OFF threshold, the device:

- Sets the CML bit in the STATUS_BYTE
- Sets the Invalid data bit in STATUS_CML
- Notifies the host via SMBALRT pin

It is the user's responsibility to make sure that chsen POWER_GOOD_ON and POWER_GOOD_OFF thresholds are reasonable with respect to each other. For values written outside the supported ranges are ACK'ed but cause the SMBALRT line to assert and the CML bit to be set in the STATUS_WORD. The invalid data bit is also set in the STATUS_CML results. The actual POWER_GOOD_OFF threshold is set to the nearest supported extreme value. For instance, with VOUT_SCALE_LOOP set to 0.5 for a typical 1.2-V output supply, setting POWER_GOOD_OFF to 0.5 results in the threshold being set to the 88% value.

The POWER_GOOD_OFF command has two data bytes formatted as two's complement binary integer:

Command		POWER_GOOD_OFF														
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r/w									r/w					
Function				High	Byte							Low	Byte			
Default Value	0	0	0	0	0	1	0	0	0	1	0	1	0	0	1	0

The default value sets the power good turn off threshold to 1.08 V which maps to the 90% low threshold and 108% high threshold.

TON_RISE (61h)

The TON_RISE command sets the time in ms, from when the output starts to rise until the voltage has entered the regulation band. There are several discreet settings that this command supports. Commanding a value other than one of these values results in the nearest supported value being selected.

The supported TON_RISE times over PMBus are as follows. Note that the actual soft-start time is longer than the entered value. Typically the nominal value seen in operation is approximately 15% longer that the time entered.

- 600 µs
- 900 µs
- 1.2 ms
- 1.8 ms

40





- 2.7 ms (default value)
- 4.2 ms
- 6.0 ms
- 9.0 ms

A value of 0 ms instructs the unit to bring its output voltage to the programmed regulation value as quickly as possible. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

The TON_RISE command is formatted as a linear mode two's complement binary integer.

Command		TON_RISE														
Format		Linear, two's complement binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		E	Exponei	nt							Mantis	sa				
Default Value	1	1	1	0	0	0	0	0	0	0	1	0	1	0	1	1

Exponent

-4 (dec), fixed.

Mantissa

The upper two bits are fixed at 0.

The lower five bits are programmable with a default value of 43 (dec)

STATUS_BYTE (78h)

The STATUS_BYTE command returns one byte of information with a summary of the most critical device faults. For TPS40400, 4 fault bits is flagged in this particular command: output over-voltage, output over-current, over-temperature, and output under-voltage. The STATUS_BYTE reports communication faults in the CML bit. Other communication faults set the NONE OF THE ABOVE bit.

Command					STATUS	BYTE							
Format		Unsigned binary											
Bit Position	7	7 6 5 4 3 2 1 0											
Access	r	r	r	r	r	r	r	r					
Function	Х	OFF	VOUT_OV	IOUT_OC	VIN_UV	TEMPERATURE	CML	NONE OF THE ABOVE					
Default Value	0	0	0	0	0	0	0	0					

A "1" in any of these bit positions indicates that:

OFF:

The device is not providing power to the output, regardless of the reason. In TPS40400, this flag means that the converter is not enabled.

VOUT_OV:

An output overvoltage fault has occurred.

IOUT_OC:

An output over current fault has occurred.

VIN_UV:

An input undervoltage fault has occurred.

TEMPERATURE:

A temperature fault or warning has occurred.



CML:

A Communications, Memory or Logic fault has occurred.

NONE OF THE ABOVE:

A fault or warning not listed in bit1 through bits 1-7 has occurred, for example an undervoltage condition or an over current warning condition

STATUS_WORD (78h)

The STATUS_WORD command returns two bytes of information with a summary of the device's fault/warning conditions. The low byte is identical to the STATUS_BYTE above. The additional byte reports the warning conditions for output overvoltage and overcurrent, as well as the power good status of the converter.

Command		STATUS_WORD (low byte)												
Format		Unsigned binary												
Bit Position	7	7 6 5 4 3 2 1 0												
Access	r	r	r	r	r	r	r	r						
Function	Х	OFF	VOUT_OV	IOUT_OC	VIN_UV	TEMPERATURE	CML	NONE OF THE ABOVE						
Default Value	0	х	0	0	0	0	0	0						

A "1" in any of the low byte (STATUS_BYTE) bit positions indicates that:

OFF:

The device is not providing power to the output, regardless of the reason. In TPS40400, this flag means that the converter is not enabled.

VOUT_OV:

An output overvoltage fault has occurred.

IOUT_OC:

An output over current fault has occurred.

VIN_UV:

An input undervoltage fault has occurred.

TEMPERATURE:

A temperature fault or warning has occurred.

CML:

A Communications, Memory or Logic fault has occurred.

NONE OF THE ABOVE:

A fault or warning not listed in bits 1-7 has occurred

Command				ST	ATUS_WORD (high byte)									
Format		Unsigned binary												
Bit Position	7	7 6 5 4 3 2 1 0												
Access	r	r	r	r	r	r	r	r						
Function	VOUT	IOUT/POUT	Х	Х	POWER_GOOD	Х	Х	Х						
Default Value	0	0	0	0	0	0	0	0						

A "1" in any of the high byte bit positions indicates that:

VOUT:

An output voltage fault or warning has occurred



IOUT/POUT:

An output current warning or fault has occurred. The PMBus specification states that this also applies to output power. TPS40400 does not support output power warnings or faults.

POWER_GOOD:

The power good signal is negated.

STATUS_VOUT (7Ah)

The STATUS_VOUT command returns one byte of information relating to the status of the converter's output voltage related faults. The only bits of this register supported by TPS40400 are VOUT_OV Fault and VOUT_UV Fault.

Command				STATUS_VC	UT			
Format				Unsigned bin	ary			
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	VOUT OV Fault	Х	Х	VOUT UV Fault	Х	Х	Х	Х
Default Value	0	0	0	0	0	0	0	0

A "1" in any of these bit positions indicates that:

VOUT OV Fault:

The device has seen the output voltage rise above the VOUT_OV_FAULT_LIMIT threshold.

VOUT UV Fault:

The device has seen the output voltage fall below the VOUT_UV_FAULT_LIMIT threshold.

STATUS_IOUT (7Bh)

The STATUS_IOUT command returns one byte of information relating to the status of the converter's output current related faults. The only bits of this register supported by TPS40400 are IOUT_OC Fault and IOUT_OC Warning.

Command				STATUS_IO	UT			
Format				Unsigned bin	ary			
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	IOUT_OV Fault	Х	IOUT OC Warning	Х	Х	Х	Х	Х
Default Value	0	0	0	0	0	0	0	0

A "1" in any of these bit positions indicates that:

IOUT_OV Fault:

The device has seen the output current rise above the level set by IOUT_OC_FAULT_LIMIT.

VOUT_UV Fault:

The device has seen the output current rise relating to the level set by IOUT_OC_WARN_LIMIT.

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STATUS_TEMPERATURE (7Dh)

The STATUS_TEMPERATURE command returns one byte of information relating to the status of the converter temperature related faults. The only bits of this register supported by TPS40400 are OT Fault and OT Warning.

Command			ST	ATUS_TEM	PERATURE			
Format				Unsigned	binary			
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	OT Fault	OT Warning	Х	Х	Х	Х	Х	Х
Default Value	0	0	0	0	0	0	0	0

A "1" in any of these bit positions indicates that:

OT Fault:

The device die temperature has exceeded the preset fault threshold.

OT Warning:

The device die temperature has exceeded the preset warning threshold.

STATUS_CML (7Eh)

The STATUS_CML command returns one byte of information relating to the status of the converter's communication related faults. The bits of this register supported by TPS40400 are:

Invalid/Unsupported Command, Invalid/Unsupported Data, Packet Error Check Failed and Other Communication Fault.

Command			STATUS_CML					
Format			Unsigned binary					
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	Invalid/Unsuppported Command	Invalid/Unsupported Data	Packet Error Check Failed	х	Х	х	Other Communication Fault	х
Default Value	0	0	0	0	0	0	0	0

A "1" in any of these bit positions indicates that:

Invalid/Unsupported Command:

An invalid or unsupported command has been received.

Invalild/Unsupported Data

Invalid or unsupported data has been received

Packet Error Check Failed

A packet has failed the CRC error check.

Other Communication Fault

Some other communication fault or error has occurred



READ_VIN (88h)

The READ_VIN commands returns two bytes of data in the linear data format that represent the input voltage applied to the VDD pin of the controller. The data format is as follows:

Command									READ_\	/IN						
Format							Lin	ear, two	o's comp	lement b	oinary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r
Function		E	Exponei	nt							Mantis	sa				
Default Value	1	1	0	1	1	0	0	0	0	0	0	0	0	0	0	0

The input voltage is scaled before it reaches the internal analog to digital converter so that resolution of the input voltage read back is 31.25mV. The input voltage can be found using Equation 25.

V_{IN} = Mantissa × 2^{Exponent} × (1+READ_VIN_CAL_GAIN)+READ_VIN_CAL_OFFSET

(25)

Exponent

Fixed at -5.

Mantissa

The lower 10 bits are the result of the ADC conversion of the input voltage. The 11th bit is fixed at 0 because only positive numbers are considered valid.

READ_VIN_CAL_GAIN comes from the MFR_SPECIFIC_06 command

READ_VIN_CAL_OFFSET comes from the MFR_SPECIFIC_07 command

READ_VOUT (8Bh)

The READ_VOUT commands returns two bytes of data in the linear data format that represent the output voltage of the controller. The output voltage is sensed at the ISNS- pin so voltage drop to the load is not accounted for. The data format is as follows:

Command								F	READ_V	JUT						
Format							Lin	ear, two	o's comp	lement b	inary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r
Function									Mantiss	sa						
Default Value	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

The setting of the VOUT_MODE affects the results of this command as well. In the TPS40400, VOUT_MODE is set to linear mode with an exponent of –10 and cannot be altered. The output voltage can be found by:

V_{OUT} = Mantissa × 2^{Exponent} × (1+READ_VOUT_CAL_GAIN)+READ_VOUT_CAL_OFFSET

(26)

Exponent

Fixed at -10 by VOUT_MODE

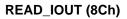
Mantissa

Bits 13 (bit 5 in high order byte) through 4 are the result of the ADC conversion of the ouput voltage. The effective LSB using this scheme is 15.625 mV.

READ_VOUT_CAL_GAIN is derived from the MFR_SPECIFIC_05 command

READ_VOUT_CAL_OFFSET is derived from the MFR_SPECIFIC_04 command

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The READ_IOUT commands returns two bytes of data in the linear data format that represent the output current of the controller. The output current is sensed at the ISNS+ and ISNS– pins. The data format is as follows:

Command								F	READ_IC	DUT						
Format							Lin	ear, two	o's comp	lement b	inary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	0 3 4 3 2 1 0 1 0 3 4 3 2 1 0 1 1 1 0 1 1 0 1 0 1 0 1 0 1														
Function		E	xpone	nt							Mantis	sa				
Default Value	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	0

The output current is scaled before it reaches the internal analog to digital converter so that resolution of the output current read is 62.5 mA, though resolution may be less depending on the setting of IOUT_CAL_GAIN. The maximum value that can be reported is 64 A. It is mandatory that the IOUT_CAL_GAIN and IOUT_CAL_OFFSET parameters are sset correctly in order to obtain accurate results. The output current can be found by using Equation 27.

 $I_{OUT} = Mantissa \times 2^{Exponent}$

Exponent

Fixed at -4.

Mantissa

The lower 10 bits are the result of the ADC conversion of the input voltage. The 11th bit is fixed at 0 because only positive numbers are considered valid.

PMBUS_REVISION (98h)

The PMBUS_REVISION command returns a single, unsigned binary byte that indicates that the TPS40400 is compliant with the 1.1 revision of the PMBus specification.

Command				PMBUS_	REVISION				
Format				Unsigne	d binary				
Bit Position	7	7 6 5 4 3 2 1 C							
Access	r	r	r	r	r	r	r	r	
Default Value	0	0	0	1	0	0	0	1	

MFR_VIN_MIN (A0h)

The MFR_VIN_MIN command returns a two-byte linear formatted result that indicates the minimum voltage from which the TPS40400 is able to convert power. The data is formatted as follows:

Command								М	FR_VIN	MIN						
Format							Lin	ear, two	o's comp	lement b	inary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	1 1 <th1< th=""> <th1< th=""> <th1< th=""> <th1< th=""></th1<></th1<></th1<></th1<>														
Function		E	Expone	nt							Mantis	sa				
Default Value	1	1	1	1	0	0	0	0	0	0	0	0	1	1	0	0

The minimum input voltage can be found using Equation 28.

 $V_{IN} = Mantissa \times 2^{Exponent}$

minimum input of 2.75-V.

This equates to 3 V when evaluated with the default values. The TPS40400 begins to convert power at a

(28)



(27)



Exponent

Fixed at -2.

Mantissa

Fixed at 12.

MFR_VIN_MAX (A1h)

The MFR_VIN_MAX returns a two-byte linear formatted result that represents the maximum voltage that the TPS40400 is specified to operate at. The data is formatted as follows:

Command								М	FR_VIN_	MAX						
Format																
Bit Position	7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r
Function		E	xpone	nt							Mantis	sa			•	
Default Value	1	1	1	1	0	0	0	0	0	1	0	1	0	0	0	0

The maximum input voltage can be found from:

 $V_{IN(min)} = Mantissa \times 2^{Exponent}$

This equals 20 V when evaluated with the default values.

Exponent

Fixed at -2.

Mantissa

Fixed at 80.

MFR_VOUT_MIN (A4h)

This command returns a two byte result that represents the minimum output voltage the TPS40400 supports.

Command								MF	R_VOU	[_MIN						
Format							Line	ear, two	o's comp	lement b	inary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r
Function									Mantiss	a						
Default Value	0	0	0	0	0	0	1	0	0	1	1	0	0	1	1	0

The setting of the VOUT_MODE affects the results of this command as well. In the TPS40400, VOUT_MODE is set to linear mode with an exponent of -10 and cannot be altered. The minimum nominal output voltage can be found by:

 $V_{OUT(max)} = Mantissa \times 2^{Exponent}$

(30)

This equals to 600 mV using the pre-set values. Using VOUT_TRIM, it is possible to adjust this voltage down to approximately 450 mV.

Exponent

Fixed at -10.

Mantissa

Fixed at 614.

(29)

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MFR_VOUT_MAX (A5h)

The command returns a two-byte result that represents the maximum output voltage that the TPS40400 supports.

Command								MF	R_VOUT	_MAX						
Format							Lin	ear, two	o's comp	lement b	inary					
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	1 1 2 1 0 1 0 1 0 1 0 1 0 1 1 1 1 1 1 1 1 1 1 1														
Function									Mantiss	sa						
Default Value	0	0	1	1	0	0	0	0	0	0	0	0	0	0	0	0

The setting of the VOUT_MODE affects the results of this command as well. In the TPS40400, VOUT_MODE is set to linear mode with an exponent of –10 and cannot be altered. The maximum nominal output voltage can be found by:

 $V_{OUT(max)} = Mantissa \times 2^{Exponent}$

This evaluates to 12 V using the pre-set values.

Exponent

Fixed at -10.

Mantissa

Fixed at 12288

MFR_SPECIFIC_00 (D0h)

The MFR_SPECIFIC_00 command is used for storing arbitrary user data and for selecting a dead time or anti-cross conduction time for the TPS40400. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

This command take a two byte unsigned binary argument as follows.

Command		MFR_SPECIFIC_00														
Format		Unsigned binary														
Bit Position	7	6 5 4 3 2 1 0 7 6 5 4 3 2 1 0											0			
Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function		USER_DATA USER_DATA WPE DTC														
Default Value	0	0 0														

Dead Time Control setting (DTC)

- 0: Fast. Dead time = \sim 25 ns
- 1: Slow. Dead time = ~ 50 ns

WPE

Write protect extension. Writing a 1 to this bit position permanently locks the following parameters:

- IOUT_CAL_GAIN
- IOUT_CAL_OFFSET
- FREQUENCY_SWITCH
- IOUT_OC_FAULT_LIMIT
- MFR_SPECIFIC_00

48



(31)



NOTE

Subsequent to setting the WPE bit, either a STORE_DEFAULT_ALL or STORE_DEFAULT_CODE (for MFR_SPECIFIC_00) PMBus command must be issued in order to prevent the WPE bit from being cleared when the device is subjected to a reset-restart operation.

MFR_SPECIFIC_01 (D1h)

This command is used for trimming internal components of the TPS40400 and is not recommended for general use.

MFR_SPECIFIC_02 (D2h)

This command is used for trimming internal components of the TPS40400 and is not recommended for general use.

MFR_SPECIFIC_03 (D3h)

This command is used for trimming internal components of the TPS40400 and is not recommended for general use.

MFR_SPECIFIC_04 (D4h)

This command applies an offset to the READ_VOUT command results to calibrate out offset errors in the on board measurement system. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		MFR_SPECIFIC_04														
Format		Linear, two's compliment binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r/w	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r/w						
Function		Mantissa														
Default Value	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0														

(1) Bits are sign extension only and are not otherwise programmable.

Default value: 0

 $\mathsf{READ_VOUT_CAL_OFFSET} = \mathsf{Mantissa} \times 2^{\mathsf{Exponent}}$

- Exponent is fixed at 2⁻¹⁰ by VOUT_MODE
- LSB value is 975 µV
- Range -125 mV to 124 mV

(32)

MFR_SPECIFIC_05 (D5h)

This command applies a gain correction to the READ_VOUT command results to calibrate out gain errors in the on board measurement system. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		MFR_SPECIFIC_05														
Format		Linear, two's compliment binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r/w	r/w	r/w	r/w	r/w
Function		E	Exponei	nt							Mantis	sa				
Default Value	1	1 0 0 0 0 1 0														

(1) Bits are sign extension only and are not otherwise programmable.

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Default value: 0

READ_VOUT_CAL_GAIN = Mantissa × 2^{Exponent}

- Exponent is fixed at -8
- LSB value is 0.4%
- Range -0.125 to 0.121

(33)

MFR_SPECIFIC_06 (D6h)

This command applies an offset to the READ_VIN command results to calibrate out offset errors in the on board measurement system. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		MFR_SPECIFIC_06														
Format		Linear, two's compliment binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r/w	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r ⁽¹⁾	r/w	r/w	r/w	r/w	r/w	r/w
Function		Exponent Mantissa														
Default Value	1	1 0 1 1 0														

(1) Bits are sign extension only and are not otherwise programmable.

Default value: 0

 $\mathsf{READ_VIN_CAL_OFFSET} = \mathsf{Mantissa} \times 2^{\mathsf{Exponent}}$

- Exponent is fixed at -5
- LSB value is 32vmV
- Range -2vV to 1.968vV

(34)

MFR_SPECIFIC_07 (D7h)

This command applies a gain correction to the READ_VIN command results to calibrate out gain errors in the on board measurement system. The contents of this register can be stored to non-volatile memory using the STORE_DEFAULT_ALL or STORE_DEFAULT_CODE commands.

Command		MFR_SPECIFIC_07														
Format		Linear, two's compliment binary														
Bit Position	7	7 6 5 4 3 2 1 0 7 6 5 4 3 2 1 0														
Access	r	r	r	r	r	r/w	r ⁽¹⁾	r/w	r/w	r/w	r/w	r/w				
Function		E	Exponei	nt							Mantis	sa				
Default Value	1	1 0														

(1) Bits are sign extension only and are not otherwise programmable.

Default value: 0

READ_VIN_CAL_GAIN = Mantissa $\times 2^{Exponent}$

- Exponent is fixed at -8
- LSB value is 0.4%
- Range -0.125V to 10.121

(35)



MFR_SPECIFIC_44 (FCh)

This command returns a two byte unsigned binary 12-bit device identifier code and 4-bit revision code in the following format.

Command		MFR_SPECIFIC_44														
Format		Linear, two's complement binary														
Bit Position	7	6	5	4	3	2	1	0	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r	r
Function		Identifier Code Revision Code														
Default Value	0	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 1 0 1 0 1														

This command is oriented toward providing similar information to the DEVICE_ID command but for devices that do not support block read and write functions.

Identifier Code

Fixed at 1 (dec)

Revision Code

Starts at 0 and increments as revisions progress.

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DESIGN EXAMPLES

Design Example 1: 12-V Input, 1.2-V Output, 20-A (max) Output Current

Design Parameters

The following example illustrates the design process and component selection for a synchronous buck converter using the TPS40400 controller. The design goal parameters are listed in Table 3.

		Design Electrical Parameters				
	PARAMETER	NOTES AND CONDITIONS	MIN	NOM	MAX	UNITS
INPUT CHAF	RACTERISTICS					
V _{IN}	Input voltage		8	12	14	V
I _{IN}	Input current	V _{IN} = 8 V, I _{OUT} = 20 A		3.6		А
	No load input current	V _{IN} = 12 V, I _{OUT} = 0 A		60		mA
V _{IN(start)}	V _{IN} start voltage			7		V
V _{IN(stop)}	V _{IN} stop voltage			5		V
	ARACTERISTICS		L.		·	
V _{OUT}	Output voltage	V _{IN} = 12 V, I _{OUT} = 20 A	1.08	1.2	1.32	V
	Line regulation	$8 \le V_{IN} \le 14 \text{ V}, I_{OUT} = 20 \text{ A}$			0.5%	
	Load regulation	$V_{IN} = 12 \text{ V}, 0 \text{ A} \le I_{OUT} \le 20 \text{ A}$			0.5%	
Vout_ripple	Output ripple voltage	V _{IN} = 12 V, I _{OUT} = 20 A			50	mV _{P-P}
lout	Output current	$8 \le V_{IN} \le 14$	0		20	А
I _{OCP}	Output over current inception point	V _{IN} = 12 V	21	25	29	А
SS	Soft-start time	(default)		2.8		ms
	Transient response					
ΔI	Load step	10 A ≤ I _{OUT} ≤ 20 A		10		А
	Load slew rate			1		A/µS
	Overshoot			120		mV
	Settling time			20		μs
SYSTEM CH	ARACTERISTICS					
f _{SW}	Switching frequency			300		kHz
η _{PK}	Peak efficiency	$V_{IN} = 12 \text{ V}, 0 \text{ A} \le I_{OUT} \le 20 \text{ A}$		90%		
η	Full load efficiency	V _{IN} = 12 V, I _{OUT} = 20 A		85%		
T _{OPER}	Operating temperature range	8 ≤ V _{IN} ≤ 14 V, 0 A ≤ I _{OUT} ≤ 20 A	-40		60	°C

Table 3. Design Electrical Parameters

Design Procedure

The following design example is for an output of 1.2 V at 20-A maximum, with an input range of 8 V to 14 V.

Selecting a Switching Frequency

This design example is calculated for a switching frequency of 300 kHz to improve efficiency. The switching frequency can be changed with the Fusion GUI, but some components may need to be revised at other switching frequencies.

Output Inductor, L_{OUT}

The output inductor value is determined by the peak-to-peak ripple at high line, and in this case a value of 30% of output current maximum is used.

$$L_{OUT} = \frac{V_{IN(max)} - V_{OUT}}{0.3 \times I_{OUT}} \times \frac{V_{OUT}}{V_{IN(max)}} \times \frac{1}{f_{SW}} = \frac{14 - 1.2}{0.3 \times 20} \times \frac{1}{300 \text{ kHz}} = 610 \text{ nH}$$

(36)



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For this design a 750-nH inductor from Pulse (PG0077.801) was selected. The actual ripple current should now be recalculated using the actual inductance value.

$$I_{\text{RIPPLE}} = di = dt \times \frac{V_{\text{L}}}{L} = 3.05\,\mu \times \frac{1.2}{0.75\,\mu} = 4.88\,\text{A}_{\text{P}-\text{P}} \tag{37}$$

With this ripple current, the inductor RMS and peak current values can be calculated.

The RMS value of a zero-average triangular wave is given by Equation 38.

$$I_{\rm RMS} = \sqrt{\left(I_{\rm DC}\right)^2 + \left(I_{\rm AC}\right)^2} = \sqrt{\left(20\right)^2 + \left(\frac{4.88}{\sqrt{12}}\right)^2} = 20.05 \,A_{\rm RMS}$$
(38)

At maximum load and maximum line, the peak inductor current is given by Equation 39.

$$I_{PEAK} = I_{DC} + \frac{I_{P-P}}{2} = 20 + \frac{4.88}{2} = 22.44 \,A_{PEAK}$$
(39)

The DCR of the selected inductor (from the data sheet) is 1.2 m Ω . Inductor conduction losses are described in Equation 40.

$$P = I^{2} \times R = (I_{RMS})^{2} \times DCR = (20.05)^{2} \times 1.2 \text{ m}\Omega = 0.482 \text{ W}$$
(40)

Output Capacitance, COUT

The selection of the output capacitor is typically affected by the output transient response requirement. Equation 41 and Equation 42 can be used to over-estimate the voltage deviation to account for delays in the loop bandwidth and can be used to determine the required output capacitance. The estimate of C_{OUT} based on overshoot is shown in Equation 41.

$$V_{\text{OVERSHOOT}} < \frac{\Delta I_{\text{OUT}}}{C_{\text{OUT}}} \times \Delta t = \frac{\Delta I_{\text{OUT}}}{C_{\text{OUT}}} \times \frac{\Delta I_{\text{OUT}} \times L_{\text{O}}}{V_{\text{OUT}}} = \frac{\left(\Delta I_{\text{OUT}}\right)^2 \times L_{\text{O}}}{V_{\text{OUT}} \times C_{\text{OUT}}}$$
(41)

The estimate of C_{OUT} based on undershoot is shown in Equation 42.

$$V_{\text{UNDERSHOOT}} < \frac{\Delta I_{\text{OUT}}}{C_{\text{OUT}}} \times \Delta t = \frac{\Delta I_{\text{OUT}}}{C_{\text{OUT}}} \times \frac{\Delta I_{\text{OUT}} \times L_{\text{O}}}{\left(V_{\text{IN}} - V_{\text{OUT}}\right)} = \frac{\left(\Delta I_{\text{OUT}}\right)^2 \times L_{\text{O}}}{\left(V_{\text{IN}} - V_{\text{OUT}}\right) \times C_{\text{OUT}}}$$
(42)

When $V_{IN(min)} > 2 \times V_{OUT}$, use the overshoot equation ($V_{Overshoot}$) to calculate minimum output capacitance. When $V_{IN(min)} < 2 \times V_{OUT}$ use the undershoot equation ($V_{Undershoot}$). In this design example, $V_{IN(min)}$ is much larger than 2 x V_{OUT} so Equation 43 is used to determine the required minimum output capacitance.

$$C_{OUT} = \frac{\left(\Delta I_{OUT}\right)^2 \times L_{OUT}}{V_{OUT} \times V_{OVERSHOOT}} = \frac{\left(10\right)^2 \times 750 \,\text{nH}}{1.2 \times 120 \,\text{mV}} = 520 \,\mu\text{F}$$
(43)

The Resistive Component of Output Ripple

With a minimum capacitance, the maximum allowable ESR is determined by the maximum ripple voltage and is approximated by Equation 44.

$$\mathsf{ESR}_{\mathsf{MAX}} = \frac{\mathsf{V}_{\mathsf{SPEC}} - \mathsf{V}_{\mathsf{RIPPLE}(\mathsf{cap})}}{\mathsf{I}_{\mathsf{RIPPLE}}} = \frac{\mathsf{V}_{\mathsf{SPEC}} - \left(\frac{\mathsf{I}_{\mathsf{RIPPLE}}}{8 \times \mathsf{C}_{\mathsf{OUT}} \times \mathsf{f}_{\mathsf{SW}}}\right)}{\mathsf{I}_{\mathsf{RIPPLE}}} = \frac{50\,\mathsf{mV} - \left(\frac{4.88}{8 \times 521\,\mu\mathsf{F} \times 300\,\mathsf{kHz}}\right)}{4.88} = 9.45\,\mathsf{m}\Omega$$
(44)

The factor of 8 in the equation above results from the calculation of capacitor voltage resulting from a triangular current. For this design, a 680- μ F, 45-m Ω ESR, 5-nH ESL tantalum and two, 47- μ F, 3-m Ω ESR, 0.9-nH ESL ceramic capacitors were selected for a total capacitance of 780 μ F.

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Peak Current Rating of the Inductor

With the output capacitance known, it is possible to calculate the charge current during start-up and determine the minimum saturation current rating for the inductor. The start-up charging current is shown in Equation 45 and the resulting peak inductor current is shown in Equation 46.

$$I_{CHARGE} = \frac{V_{OUT} \times C_{OUT}}{t_{SS}} = \frac{1.2 \times (680 \,\mu + 2 \times 47 \,\mu)}{3.1 \,\text{m}} = 0.3 \,\text{A}$$
(45)

$$I_{L1(peak)} = I_{OUT(max)} + \left(\frac{I_{RIPPLE}}{2}\right) + I_{CHARGE} = 20 + \left(\frac{4.88}{2}\right) + 0.3 = 23.04 \text{ A}$$
(46)

Input Capacitance, C_{IN}

The input capacitor is selected to limit the input ripple voltage to 20% or less of V_{IN} . The ripple voltage is due to the current flowing in the input capacitor's ESR as well as capacitance charging and discharging. To simplify the calculations, an infinitely large series input inductance is assumed. With an infinite inductor, the input capacitor current is calculated to be 5.6 Arms.

For reasons of availability, consider the capacitor EEVFC1E331P, which is an electrolytic, $330-\mu$ F, 25-V capacitor with 150-m Ω of ESR and 100-nH ESL. This capacitor has an rms current rating of 670 mA. With the calculated rms value of the capacitor current of 5.6 Arms, this implies that needs to be additional capacitance with a much lower ESR across the input bus in order to divert most of the AC current to this low ESR capacitor.

Another readily available capacitor is selected. A 22- μ F, ceramic, 25-V, 10-m Ω ESR, 0.9-nH ESL device, two in parallel. With these capacitors in parallel, the ripple in the electrolytic is well within its rating with a value of 329 mA_{rms}.

Switching MOSFETs, Q_{HS} and Q_{LS}

The high-side and low-side FETs, Q_{HS} and Q_{LS}, are selected based on several factors including:

- · Vds, the drain to source voltage rating. This design requires a 25-V device
- Vgs, the gate to source voltage rating. For the TPS40400 this voltage is 6.5 V
- Conduction losses, based on I²×R_{DS(on)}
- Gate charge, must be low enough to be driven by the PWM controller

These devices are selected:

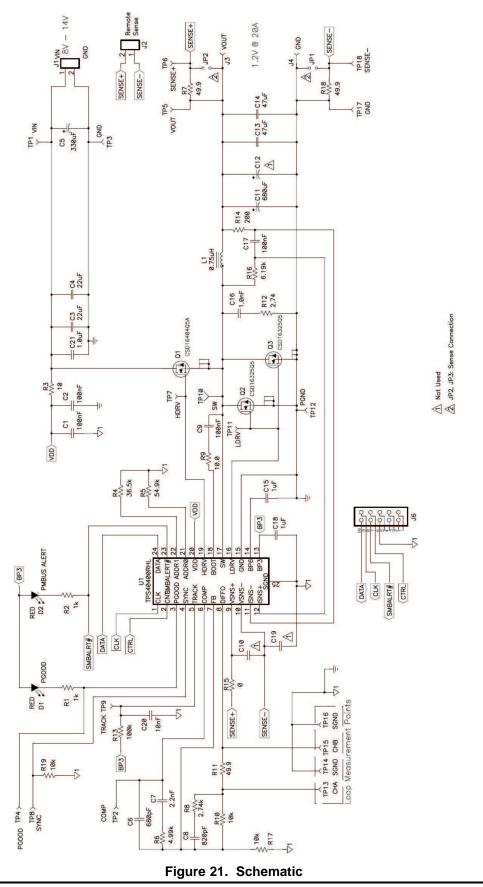
LOCATION	PART NUMBER	VOLTAGE RATING (V)	R _{DS(on)} (mΩ)	GATE CHARGE Q _G (nC)	QTY
High-side	CSD16404Q5A	25	4.1	8	1
Low-side	CSD16325Q5	25	1.7	25	2

Since the selected FETs are very fast, the controller is programmed to have the shorter dead-time of 25 ns.

General Component Selection

Refer to the schematic in Figure 21 for device reference designators and connections for the TPS40400 Design Example 1.





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Device Addressing, R_{ADDR0} and R_{ADDR1}

The PMBus address for the device must be read from the ADDR0 and ADDR1 pins. Each pin has an internal fixed current source and the resulting developed voltage is read and converted to the desired device address. The external resistors RADDR0 and RADDR1 from the address pins to ground set eight possible states for a total of 64 possible addresses. The address states are determined by voltages on the address pins per Table 4.

Table 4. Address Configuration

DIGIT 0

1

2

3

4

5

6

7

RESISTANCE (kΩ)

10

15.4

23.7

36.5

54.9

84.5

130 200

For this design, the address of 34 octal,	or 28 decimal is selected arbitrarily. In order to achieve this address, the
ADDR0 resistor R5 would be 54.9 kΩ ar	nd the ADDR1 resistor R4 would be 36.5 k Ω .

Current Sense Flter, R16 and C17

Current sensing for the TPS40400 is typically done by sensing the voltage drop across the output inductor's (L1) DC resistance. In order to do this, the large AC switching voltage forced across L1 must be filtered out so that the measured voltage is only the DC drop. This is done by placing an R-C filter directly across the output choke (high-frequency filter) L1. The R-C combination is chosen such that it provides enough filtering for the application and the time constant is chosen to match that of the output inductor and its ESR, which is shown in Equation 47.

$$\tau = \frac{L1}{DCR}$$
(47)

Usually a capacitor value is chosen between 10 nF and 1 µF for this location. A value of 100 nF is arbitrarily chosen, which yields Equation 48.

$$R16 = \frac{L1}{DCR} \times \frac{1}{C} = \frac{750 \text{ nH}}{1.2 \text{ m}\Omega \times 100 \text{ nF}} = 6.25 \text{ k}\Omega$$
(48)

Choose a standard value of 6.19 k Ω .

The capacitor C17 should be placed as close to the ISNS+ and ISNS- pins as possible to provide good bypass filtering. R16 should be placed close to the inductor to prevent traces with the switch node voltage from being propagated across the PCB and getting close to sensitive pins of the TPS40400.

Voltage Decoupling Capacitors, C_{BP3}, C_{BP6}, and C_{VDD}

Three pins on the TPS40400 have DC bias voltages. It is necessary to add small decoupling capacitors to these pins. Table 5 shows the recommended minimum values.

DEVICE LOCATION	RECOMMENDED MINIMUM VALUE	FUNCTION	SELECTED VALUE
C _{BP3} , (C18)	0.1-µF low ESR	V_{CC} for internal controls of the device	1-µF ceramic
C _{BP6} , (C15)	1-µF low ESR	V _{CC} for gate drivers	1-µF ceramic
C _{VDD} , (C1) and (C2)	0.1-µF low ESR	$V_{\mbox{CC}}$ for input power to the device	$2 \ x \ 100 \ nF,$ with additional series $10 \ \Omega$ filter resistor R3 to filter out switching noise from the power FETs

Table 5. Voltage Decoupling Capacitor Values



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Bootstrap Capacitor, C9

Selection of the bootstrap capacitor is based on the total gate charge of the high-side FET and the allowable ripple on the BOOT pin. A ripple of 0.2 V is chosen as maximum for this design. This yields a value described in Equation 49.

$$C_{\text{BOOT}} = C9 \ge \frac{Q_{\text{GHS}}}{V_{\text{BOOT}(\text{ripple})}} \times \frac{8nC}{0.2V} = 40\,\text{nF}$$
(49)

Choose a standard value of 100 nF. Additionally, a series resistor R9 is added in order to reducing the turn-on speed of the high-side FET, Q1.

Snubber R12 and C16

For this design, the snubber function is designed based on an allowable snubber power dissipation. A target value of between 0.25% and 0.5% of the rated output power (P_{OUT}) is used as the starting point for the calculation of the snubber values. Once the snubber values are determined and real hardware is obtained, the snubber values can be adjusted to achieve better results.

$$\frac{\text{Energy}}{\text{sec onds}} = \frac{\text{E}}{\text{cycle}} \times f_{\text{SW}} = 2(\text{events}) \times \frac{1}{2} \times \text{C} \times \text{V}^2 \times 300 \,\text{kHz}$$
(50)

$$C = \frac{60 \text{mW}}{\text{V}^2 \times 300 \text{kHz}} = \frac{60 \text{mW}}{196 \times 300 \text{kHz}} = 1.02 \text{nF}$$
(51)

Shortest Pulse Width

$$R = \frac{10}{5 \times C} = \frac{28.6n}{5 \times C} = \frac{28.6n}{5 \times 1n} = 5.72 \Omega$$
(52)

Loop Compensaton Components

Using the Texas Instruments SwitcherPro[™] design tool and the resulting plant (system) bode plot, a crossover frequency of 20 kHz is selected with 45° of phase margin. The resulting compensation components are listed in Table 6.

COMPONENT LOCATION	VALUE
R6	4.99 kΩ
R8	2.74 kΩ
C6	680 pF
C7	2.2 nF
C8	820 pF

Table 6. Deisgn Example 1 Component Summary

Output Voltage Set Point, RBIAS

The output voltage can be set by choosing and calculating R1 and R_{BIAS} . The V_{OUT} set point is shown in Equation 53.

$$R_{BIAS} = \frac{V_{REF} \times R1}{V_{OUT} - V_{REF}}$$
(53)

In this design R1 was chosen to be 10 k Ω . R_{BIAS} is calculated to be 10 k Ω .

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Remote Sensing

Remote sensing can be accomplished with the differential amplifier as shown in Figure 22. Resistors RS1 and RS2 (R7 and R18 in the schematic above) are used if the sense connections fail or get damaged. The values of RS1 and RS2 are bound by an upper value such that the voltage drop across them does not introduce appreciable voltage regulation error from the bias current, and a lower value such that the voltage drop in the load wires which appears across these resistors does not dissipate appreciable power. Values between 10 Ω to 50 Ω are usually chosen.

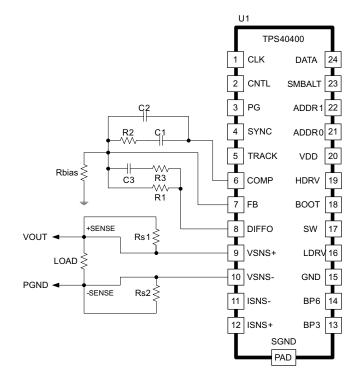


Figure 22. Remote Sense Schematic



Typical Performance Characteristics

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Gain

Phase

Reference

140

120

100

96 70 $f_{SW} = 300 \text{ k}\Omega$ 60 94 50 92 40 Efficiency (%) Gain (dB) 30 90 20 88 10 86 0 -10 84 $V_{IN} = 8 V$ $I_{OUT} = 20 \text{ A}$ -20 V_{IN} = 12 V $V_{IN} = 14 V$ 82

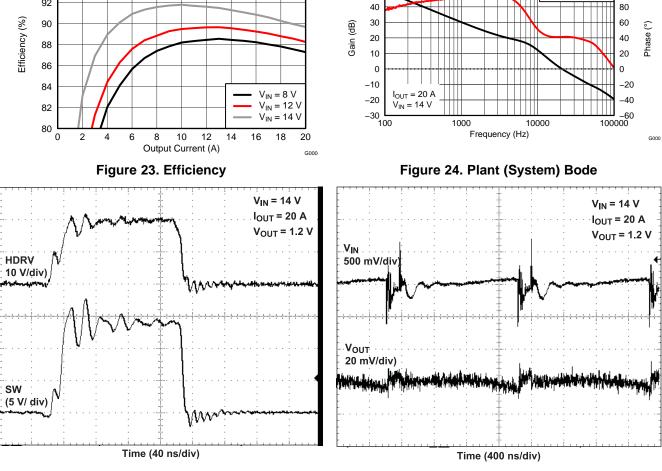


Figure 25. Switching Waveform

Figure 26. Ripple Waveform

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Design Example 1 List of Materials

Table 7 lists of materials for Design Example 1.

REFERENCE DESIGNATOR	QTY	VALUE	DESCRIPTION	SIZE	PART NUMBER	MFR
C1, C2, C9, C17	4	100 nF	Ceramic, 25 V, X7R, 10%	0603	Std	Std
C11	1	680 µF	Tantalum, 6.3 V, 10%	7343 (D)	TPSE687K006R004 5	AVX
C13, C14	2	47 µF	Ceramic, 6.3 V, X7R, 10%	1210	Std	Std
C15, C18	2	1 μF	Ceramic, 16 V, X7R, 10%	0805	Std	Std
C16	1	1.0 nF	Ceramic, 25 V, X7R, 10%	0603	Std	Std
C20	1	10 nF	Ceramic, 50 V, X7R, 10%	0603	Std	Std
C21	1	1.0 µF	Ceramic, 25 V, X7R, 10%	1206	Std	Std
C3, C4	2	22 µF	Ceramic, 25 V, X7R, 10%	1210	Std	Std
C5	1	330 µF	Aluminum, 25 V, 150 m Ω , FC series	10 mm x 12 mm	EEVFC1E331P	Panasonic
C6	1	680 pF	Ceramic, 50 V, X7R, 10%	0603	Std	Std
C7	1	2.2 nF	Ceramic, 50 V, X7R, 10%	0603	Std	Std
C8	1	820 pF	Ceramic, 50 V, X7R, 10%	0603	Std	Std
D1, D2	2	RED	LED, Red, 20-mA, 6-mcd	0603	LTST-C190CKT	Lite On
J1, J2	2	D120/2DS	Terminal block, 2-pin, 15-A, 5.1mm	0.40 inch x 0.35 inch	ED120/2DS	On Shore Technology
J3, J4	2	L35	Type L - copper single conductor, one-hole mount	0.813 inch x 0.375 inch	L35	Thomas and Betts
J6	1	86479-3	Male right angle 2 x 5-pin, 100mil spacing	0.607 inch x 0.484 inch	86479-3	AMP
JP1, JP2	2	PEC02SAAN	Header, 2-pin, 100 mil Spacing	0.100 inch x 2	PEC02SAAN	Sullins
L1	1	0.75 µH	Inductor, SMT, 0.75 μH, 1.2 mΩ, 31A	0.512 x 0.571 inch	PG0077.801	Pulse
Q1	1	CSD16404Q5 A	MOSFET, N-channel, 25 V, 20 A, 4.1 m Ω	QFN5X6mm	CSD16404Q5A	ті
Q2, Q3	2	CSD16325Q5	MOSFET, N-channel, 25 V, 33 A, 1.7 m Ω	QFN-8 POWER	CSD16325Q5	ті
R1, R2	2	1 kΩ	Resistor, 1/16-W, 5%	0603	Std	Std
R10, R17, R19	3	10 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R12	1	2.74 kΩ	Resistor, 1/8W, 1%	1206	Std	Std
R13	1	100 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R14	1	200 Ω	Resistor, 1/16W, 1%	0603	Std	Std
R15	1	0 Ω	Resistor, 1/16W, 1%	0603	Std	Std
R16	1	6.19 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R3, R9	2	10 Ω	Resistor, 1/16W, 1%	0603	Std	Std
R4	1	36.5 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R5	1	54.9 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R6	1	4.99 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
R7, R11, R18	3	49.9 Ω	Resistor, 1/16W, 1%	0603	Std	Std
R8	1	2.74 kΩ	Resistor, 1/16W, 1%	0603	Std	Std
U1	1	TPS40400RH L	3.0 V to 20 V PMBus synchronous buck controller	QFN-24	TPS40400RHL	ТІ

Table 7. List of Materials



Internal Configuration

Internal configuration of the TPS40400 is handled via the PMBus (pins CLK and DATA) and the Fusion Digital Power Designer (GUI interface). An example of the configuration window that is used to make internal configuration changes to the TSP40400 is shown below in Figure 27.

	Advanced Configuration							
adware	Command	Code	Value/Edit	Hex/Edit	Command	Code	Value/Edit	Hex/Edit
e on rail or	▼ Calibration				▼ On/Off Configuration	11.46.24		
ange	IOUT_CAL_GAIN	0x38	0.0021 🔁 g	0x9811	ON_OFF_CONFIG	0x02	0x03 🖂	0x03
hanges	IOUT_CAL_OFFSET	0x39	0.0000 🔁 A	0×E000	OPERATION	0x01	0x00 🔽	0x00
To Plash	VOUT_SCALE_LOOP	0x29	0.500 🕀	0x8200	POWER_GOOD_OFF	0x5F	1.080 🖶 V	0x0452
tito RMA	YOUT_TRIM	0x22	0.000 🕀 v	0x0000	POWER_GOOD_ON	0×5E	1.104 🕀 V	0x046A
	▼ Configuration				TON_RISE	0x61	2.6250 🐳 ms	0xE02A
e Notices	FREQUENCY_SWITCH	0x33	294,912.0 🚍 K	hz 0x7809	▼ Status			
ers By:	TRIM_CONTROL [MFR 01]	0xD1	0×10EE	0×10EE	READ_IOUT	0x8C	0.13 A	0xE002
nd Name	TRIM_GENERAL [MFR 00]	0xD0	0x8ED1	0x8ED1	READ_VIN	0x88	3.156 V	0xD865
nd Code	TRIM_GM_AMP_ISENSE [MFR 02]	0x02	0x9071	0x9071	READ_VOUT	0x88	1.094 V	0×D823
Category	VOUT_MARGIN_HIGH	0x25	1.319 🕀 v	0x0547	STATUS_BYTE	0x78	0x02 🖳	0x02
	YOUT_MARGIN_LOW	0x26	1.079 🕀 v	0x0451	STATUS_CML	0×7E	0x02 💌	0x02
	VOUT_MODE	0x20	EXP -10	0×16	STATUS_IOUT	0x78	0x00 💌	0x00
	WRITE_PROTECT	0x10	0x00 🔽	0x00	STATUS_TEMPERATURE	0x70	0x00 🖂	0x00
	▼ Limits				STATUS_VOUT	0x7A	0x00 🖂	0x00
	IOUT_OC_FAULT_LIMIT	0x46	25.0 🕀 A	0xF832	STATUS_WORD	0x79	0x0002 🔽	0::0002
	IOUT_OC_FAULT_RESPONSE	0x47	0xC0 🔽	0xC0				
	IOUT_OC_WARN_LIMIT	0x4A	21.0 🗮 A	0xF82A				
	OT_FAULT_RESPONSE	0x50	0x00 💌	0x00				
	VIN_OFF	0x36	2.50 🕀 v	0xF00A				
	VIN_ON	0x35	2.75 🖶 v	0xF00B				
	VOUT_OV_FAULT_LIMIT	0x40	1.560 🕀 v	0x063D				
	VOUT_OV_FAULT_RESPONSE	0x41	0x00 🔽	0x00				
	YOUT_UY_FAULT_LIMIT	0x44	1.140 🖶 V	0x048F				
	VOUT_UV_FAULT_RESPONSE	0x45	0x00 🔽	0x00				
	▼ Manufacturer Info							
	VIN_ON [0x35]		Tr	ansaction Log				
	Voltage at which power conversion starts.			10 / 11 / 10 / 10 / 10 / 10 / 10 / 10 /				
<u>6</u> .								
ure			~					

Figure 27. Advanced Configuration Window

Figure 27 shows are the user changeable parameters of the TPS40400 and these consist of the following sections.

- Calibration
- Configuration
- Limits
- On/Off Configuration

The status section is read only, and consists of data read from the TPS40400 such as V_{OUT} , I_{OUT} , V_{IN} , and status words. A full description of each command and status word is available in the SUPPORTED COMMANDS section of the TPS40400 datasheet.

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Configuration changes can be implemented by changing the value in the **Value/Edit** box of each parameter. Most boxes allow direct parameter changes such as voltage or current, but some boxes such as **IOUT_OC_FAULT_RESPONSE** provide a pop-up configuration window as shown in Figure 28, and others provide a pull-down menu. Select the appropriate radio buttons to make the desired changes.

To implement the changes to the device, click on the [Write to Hardware] button. This stores the changes to the device in volatile memory, so these changes are lost when input power is cycled. To permanently make changes and commit those changes to non-volatile memory, click on the [Store RAM to Flash] button.

	sponse
OC	ontinue Without Interruption
CI	he device continues to operate indefinitely while maintaining the output urrent at the value set by IOUT_OC_FAULT_LIMIT without regard to the utput voltage (known as constant-current or brickwall limiting).
T c v I t	Taintain Output Current Per Limits he device continues to operate indefinitely while maintaining the output urrent at the value set by IOUT_OC_FAULT_LIMIT as long as the output oltage remains above the minimum value specified by DUT_OC_UV_FAULT_LIMIT. If the output voltage is pulled down to less nan this value, the device shuts down and restarts per the configuration elow.
00	ontinue Operation For 👘 💿 🗧 ms
v v lii	he device continues to operate, maintaining the output current at the value set by IOUT_OC_FAULT_LIMIT without regard to the output voltage, for the specified time. If the device is still operating in current miting at the end of the delay time, the device responds as programmed velow.
0 5	hut Down Immediately
	he device shuts down immediately (disables the output); configure restar elow.
D	
10	start
Re	
-Re OD	start
Re: OD Ti fa	start Yo Not Restart he unit does not attempt to restart. The output remains disabled until the
- Re: O D Ti fa	start No Not Restart he unit does not attempt to restart. The output remains disabled until the sult is cleared.
Re: D Ti fa R Ti If ti	start No Not Restart he unit does not attempt to restart. The output remains disabled until the ault is cleared. testart Up To 4 - Times he device attempts to restart up to the specified number of times. the device fails to restart (the fault condition is no longer present and
Res D Tl fa R Tl If th u	start by Not Restart the unit does not attempt to restart. The output remains disabled until the ault is cleared. testart Up To 4 Times the device attempts to restart up to the specified number of times. the device is delivering power to the output and operating as programmed the allowed number of retries, it disables the output and remains off
Ref D T f f r R T I f t t t t t t t t t t t t t t t t t t	start by Not Restart the unit does not attempt to restart. The output remains disabled until the ault is cleared. testart Up To 4 3 Times the device attempts to restart up to the specified number of times. it the device fails to restart (the fault condition is no longer present and the device delivering power to the output and operating as programmed the allowed number of retries, it disables the output and remains off ntil the fault is cleared.

Figure 28. IOUT_OC_FAULT_RESPONE Configuration Window



Design Example 2: 12-V Input, 5-V Output, 5-A (max) Output Current

Design Example 2 Parameters

The following example illustrates the design process and component selection for a synchronous buck converter using the TPS40400 controller. The design goal parameters are listed in Table 8.

	PARAMETER	NOTES AND CONDITIONS	MIN	NOM	MAX	UNITS
INPUT CHAP	RACTERISTICS					
V _{IN}	Input voltage		8	12	14	V
I _{IN}	Input current	V _{IN} = 8 V, I _{OUT} = 5 A		3.5		А
	No load input current	V _{IN} = 12 V, I _{OUT} = 0 A		60		mA
V _{IN(start)}	V _{IN} start voltage			7		V
V _{IN(stop)}	V _{IN} stop voltage			6		V
	ARACTERISTICS		·		·	
V _{OUT}	Output voltage	V _{IN} = 12 V, I _{OUT} = 5 A	4.75	5.00	5.25	V
	Line regulation	$8 \le V_{IN} \le 14 \text{ V}, I_{OUT} = 5 \text{ A}$			0.5%	
	Load regulation	$V_{IN} = 12 \text{ V}, 0 \text{ A} \le I_{OUT} \le 5 \text{ A}$			0.5%	
Vout_ripple	Output ripple voltage	V _{IN} = 12 V, I _{OUT} = 5 A			50	mV_{P-P}
lout	Output current	8 ≤ V _{IN} ≤ 14	0		5	А
I _{OCP}	Output over current inception point	V _{IN} = 12 V	6.7	8.0	9.3	А
SS	Soft-start time	(default)		5		ms
	Transient response					
ΔI	Load step	2 A ≤ I _{OUT} ≤ 5 A		3		А
	Load slew rate			1		A/µS
	Overshoot			500		mV
	Settling time			50		μs
SYSTEM CH	ARACTERISTICS					
f _{SW}	Switching frequency			300		kHz
η _{PK}	Peak efficiency	$V_{IN} = 12 \text{ V}, 0 \text{ A} \le I_{OUT} \le 5 \text{ A}$		90%		
η	Full load efficiency	V _{IN} = 12 V, I _{OUT} = 5 A		85%		
T _{OPER}	Operating temperature range	$8 \le V_{IN} \le 14 V$, $0 A \le I_{OUT} \le 5 A$	-40		60	°C

Table 8. Design Example 2 Electrical Parameters

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General Component Selection

Refer to the schematic below for device reference designators and connections.

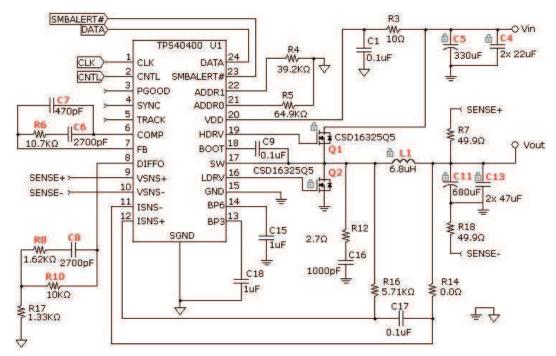


Figure 29. Design Example 2 Schematic



Design Example 2 List of Materials

Table 9 lists of materials for Design Example 2.

REFERENCE DESIGNATOR	QTY	VALUE	DESCRIPTION	SIZE	PART NUMBER	MFR
C1, C2, C9, C17	4	0.1 µF	Ceramic, X7R, 25 V, 20%	0603	Standard	Standard
C3, C4	2	22 µF	Ceramic, X7R, 25 V, 10%	1210	Standard	Standard
C5	1	330 µF	Aluminum, 25 V, 20%	10x12mm	EEVFC1E331P	Panasonic
C6	1	2700 pF	Ceramic, X7R, 10 V, 20%	0603	Standard	Standard
C7	1	470 pF	Ceramic, X7R, 10 V, 20%	0603	Standard	Standard
C8	1	2700 pF	Ceramic, X7R, 10 V, 20%	0603	Standard	Standard
C11	1	680 µF	Tantalum, 6.3 V, 20%	7343 (D)	TPSE6870060045	Standard
C13, C14	2	47 µF	Ceramic, X7R, 6.3 V, 20%	1210	GRM32ER60J476M	Standard
C15, C18	2	1 µF	Ceramic, X7R, 16 V, 20%	0603	Standard	Standard
C16	1	1000 pF	Ceramic, X7R, 25 V, 20%	0603	Standard	Standard
L1	1	6.8 µH	Inductor, 6.8 μH, 12 mΩ		PF0553.682NL	Pulse
Q1	1	CSD16325Q5	Transistor, N-channel FET, 25 V, 100 A, 10 Ω	QFN 5x6	CSD16325Q5	TI
Q2	1	CSD16325Q5	Transistor, N-channel, 25 V, 100 A, 10 Ω	QFN 5x6	CSD16325Q5	TI
R3	1	10 Ω	Resistor, 1/16W, 5%	0603	Standard	Standard
R4	1	39.2 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R5	1	64.9 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R6	1	10.7 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R7, R18	2	49.9 Ω	Resistor, 1/16W, 1%	0603	Standard	Standard
R8	1	1.62 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R10	1	10 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R12	1	2.7 Ω	Resistor, 1/16W, 5%	0603	Standard	Standard
R14	1	0.0 Ω	Resistor, 1/16W, 1%	0603	Standard	Standard
R16	1	5.71 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
R17	1	1.33 kΩ	Resistor, 1/16W, 1%	0603	Standard	Standard
U1	1	TPS40400	3.0V-20V PMBus synchronous buck controller	24-pin QFN	TPS40400RHL	Texas Instruments

Table 9. Design Example 2 List of Materials

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Design Characterization

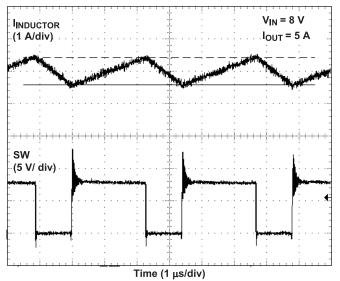


Figure 30. Switching Voltage and Inductor Current Waveform

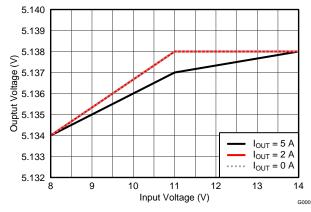
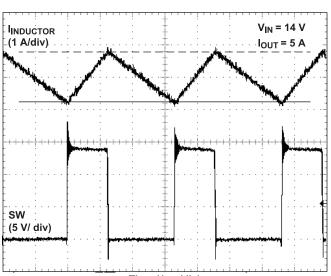


Figure 32. Design Example 2 Line Regulation



Time (1 µs/div)

Figure 31. Switching Voltage and Inductor Current Waveform

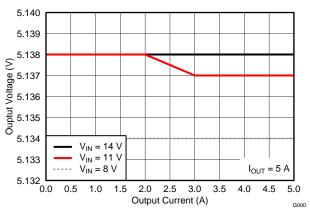


Figure 33. Design Example 2 Load Regulation



REVISION HISTORY

Cł	Inges from Revision A (JULY 2011) to Revision B P						
•	Changed corrected default values in ON_OFF_CONFIG table.	24					
•	Added Design Example 1	52					
•	Added Design Example 2	63					

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



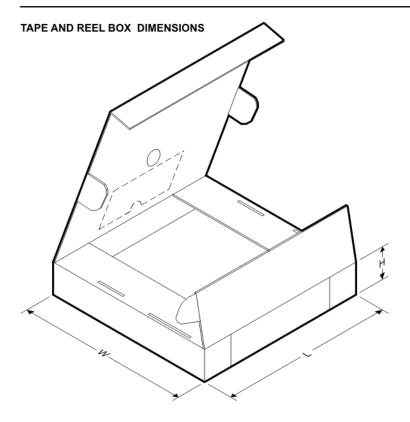
All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS40400RHLR	VQFN	RHL	24	3000	330.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1
TPS40400RHLT	VQFN	RHL	24	250	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

16-Oct-2020



*All dimensions are nominal

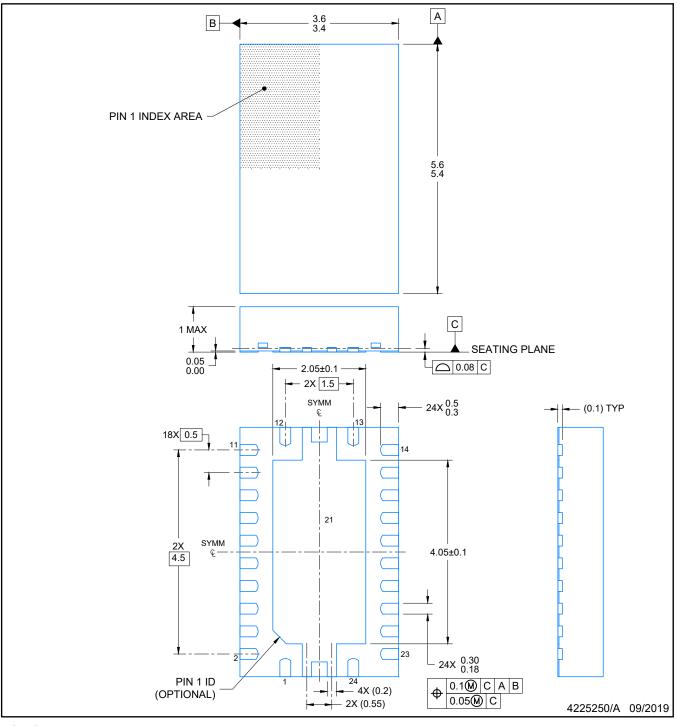
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS40400RHLR	VQFN	RHL	24	3000	853.0	449.0	35.0
TPS40400RHLT	VQFN	RHL	24	250	210.0	185.0	35.0

RHL0024A

PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

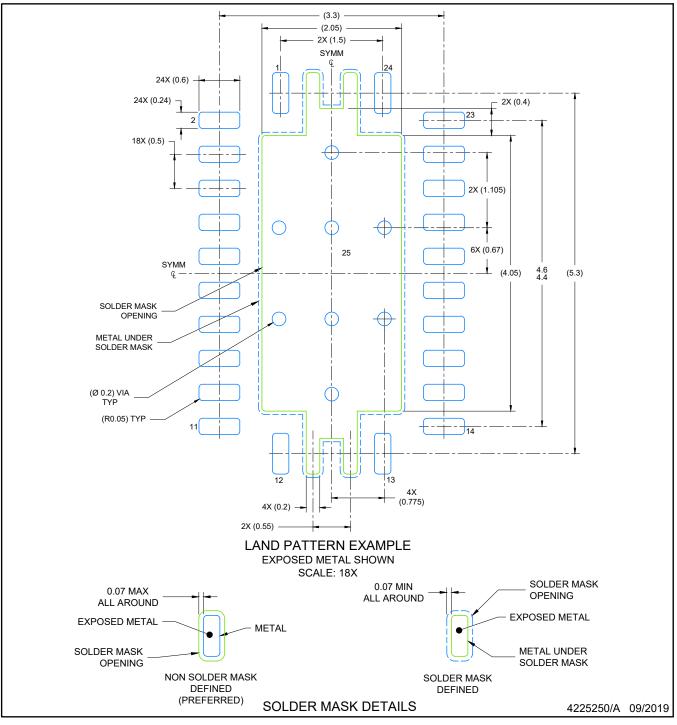


RHL0024A

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

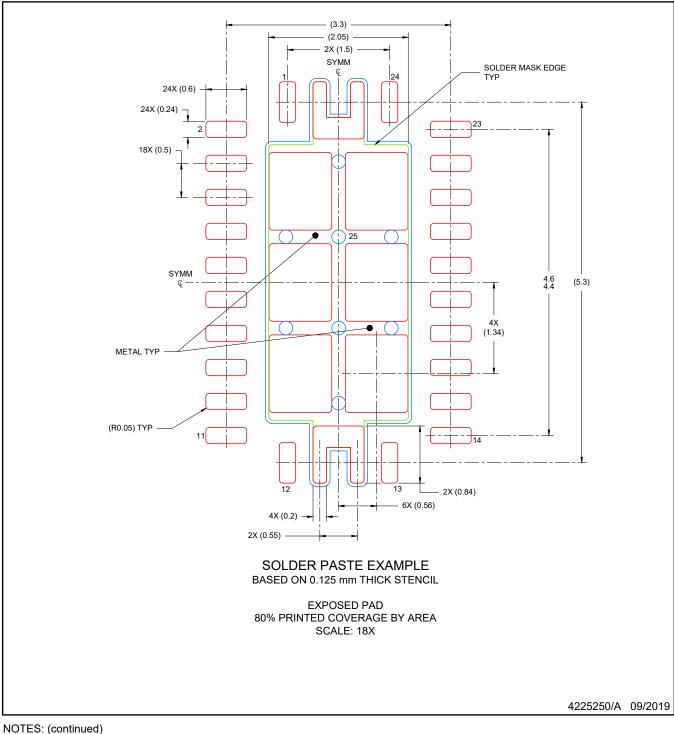


RHL0024A

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK- NO LEAD



6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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